

# LTC2063/LTC2064/LTC2065

## ABSOLUTE MAXIMUM RATINGS

(Note 1)

Total Supply Voltage ( $V^+$  to  $V^-$ ) ..... 5.5V  
 Differential Input Current (+IN to -IN) (Note 2) ....  $\pm 10\text{mA}$   
 Differential Input Voltage (+IN to -IN) ..... 5.5V  
 Input Voltage +IN, -IN,  $\overline{\text{SHDN}}$  ( $V^-$ ) - 0.3V to ( $V^+$ ) + 0.3V  
 Input Current +IN, -IN,  $\overline{\text{SHDN}}$  (Note 2) .....  $\pm 10\text{mA}$   
 Output Short-Circuit Duration (Note 3) ..... Thermally Limited

Operating and Specified Temperature Range (Note 4)

LTC2063I/LTC2064I/LTC2065I ..... -40°C to 85°C

LTC2063H/LTC2064H/LTC2065H ..... -40°C to 125°C

Maximum Junction Temperature ..... 150°C

Storage Temperature Range ..... -65°C to 150°C

## PIN CONFIGURATION

|                                                                                                                         |                                                                                                                                                                                                                                                                                 |                                                                                                                                                                                     |
|-------------------------------------------------------------------------------------------------------------------------|---------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|-------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| <p>LTC2063</p> <p>SC6 PACKAGE<br/>6-LEAD PLASTIC SC70<br/><math>\theta_{JA} = 265^\circ\text{C/W}</math> (Note 5)</p>   | <p>LTC2064</p> <p>DD PACKAGE<br/>10-LEAD (3mm x 3mm) PLASTIC DFN<br/><math>\theta_{JA} = 43^\circ\text{C/W}</math>, <math>\theta_{JC} = 5.5^\circ\text{C/W}</math> (Note 5)<br/>EXPOSED PAD (PIN 11) IS CONNECTED TO <math>V^-</math> (PIN 4)<br/>(PCB CONNECTION OPTIONAL)</p> | <p>LTC2065</p> <p>QFN16 PACKAGE<br/>16-LEAD (3mm x 3mm) PLASTIC QFN<br/><math>\theta_{JA} = 68^\circ\text{C/W}</math> (NOTE 5)<br/>EXPOSED PAD IS CONNECTED TO <math>V^-</math></p> |
| <p>LTC2063</p> <p>S5 PACKAGE<br/>5-LEAD PLASTIC TSOT-23<br/><math>\theta_{JA} = 215^\circ\text{C/W}</math> (Note 5)</p> | <p>LTC2064</p> <p>MS8 PACKAGE<br/>8-LEAD PLASTIC MSOP<br/><math>\theta_{JA} = 163^\circ\text{C/W}</math>, <math>\theta_{JC} = 40^\circ\text{C/W}</math> (Note 5)</p>                                                                                                            | <p>LTC2065</p> <p>TSSOP14 PACKAGE<br/>14-LEAD PLASTIC TSSOP<br/><math>\theta_{JA} = 100^\circ\text{C/W}</math> (NOTE 5)</p>                                                         |

## ORDER INFORMATION

| TAPE AND REEL (MINI) | TAPE AND REEL     | PART MARKING* | PACKAGE DESCRIPTION             | TEMPERATURE RANGE |
|----------------------|-------------------|---------------|---------------------------------|-------------------|
| LTC2063ISC6#TRMPBF   | LTC2063ISC6#TRPBF | LGTX          | 6-Lead Plastic SC70             | -40°C to 85°C     |
| LTC2063HSC6#TRMPBF   | LTC2063HSC6#TRPBF | LGTX          | 6-Lead Plastic SC70             | -40°C to 125°C    |
| LTC2063IS5#TRMPBF    | LTC2063IS5#TRPBF  | LTGTW         | 5-Lead Plastic TSOT-23          | -40°C to 85°C     |
| LTC2063HS5#TRMPBF    | LTC2063HS5#TRPBF  | LTGTW         | 5-Lead Plastic TSOT-23          | -40°C to 125°C    |
| LTC2064IMS8#TRMPBF   | LTC2064IMS8#TRPBF | LTHCX         | 8-Lead Plastic MSOP             | -40°C to 85°C     |
| LTC2064HMS8#TRMPBF   | LTC2064HMS8#TRPBF | LTHCX         | 8-Lead Plastic MSOP             | -40°C to 125°C    |
| LTC2064IDD#TRMPBF    | LTC2064IDD#TRPBF  | LHCW          | 10-Lead (3mm x 3mm) Plastic DFN | -40°C to 85°C     |
| LTC2064HDD#TRMPBF    | LTC2064HDD#TRPBF  | LHCW          | 10-Lead (3mm x 3mm) Plastic DFN | -40°C to 125°C    |

Rev. B

## ORDER INFORMATION

| TAPE AND REEL (MINI) | TAPE AND REEL    | PART MARKING* | PACKAGE DESCRIPTION             | TEMPERATURE RANGE |
|----------------------|------------------|---------------|---------------------------------|-------------------|
| LTC2065IUD#TRMPBF    | LTC2065IUD#TRPBF | LHKT          | 16-Lead (3mm × 3mm) Plastic QFN | –40°C to 85°C     |
| LTC2065HUD#TRMPBF    | LTC2065HUD#TRPBF | LHKT          | 16-Lead (3mm × 3mm) Plastic QFN | –40°C to 125°C    |
| LTC2065IF#TRMPBF     | LTC2065IF#TRPBF  | LTC2065       | 14-Lead TSSOP                   | –40°C to 85°C     |
| LTC2065HF#TRMPBF     | LTC2065HF#TRPBF  | LTC2065       | 14-Lead TSSOP                   | –40°C to 125°C    |

Consult ADI Marketing for parts specified with wider operating temperature ranges. \*The temperature grade is identified by a label on the shipping container. Parts ending with PBF are RoHS and WEEE compliant.

[Tape and reel specifications](#). Some packages are available in 500 unit reels through designated sales channels with #TRMPBF suffix.

## ELECTRICAL CHARACTERISTICS

The ● denotes the specifications which apply over the full operating temperature range, otherwise specifications are at  $T_A = 25^\circ\text{C}$ . Unless otherwise noted,  $V_S = 1.8\text{V}$ ,  $V_{CM} = V_{OUT} = V_S/2$ ,  $V_{SHDN} = 1.8\text{V}$ ,  $R_L$  to  $V_S/2$ .

| SYMBOL                   | PARAMETER                                     | CONDITIONS                                                                     | MIN    | TYP           | MAX                      | UNITS                                                        |
|--------------------------|-----------------------------------------------|--------------------------------------------------------------------------------|--------|---------------|--------------------------|--------------------------------------------------------------|
| $V_{OS}$                 | Input Offset Voltage (Note 6)                 | $V_S = 1.7\text{V}$                                                            | ●      | 1             | $\pm 5$<br>$\pm 10$      | $\mu\text{V}$<br>$\mu\text{V}$                               |
| $\Delta V_{OS}/\Delta T$ | Input Offset Voltage Drift (Note 6)           | –40°C to 85°C<br>–40°C to 125°C                                                | ●<br>● |               | $\pm 0.03$<br>$\pm 0.06$ | $\mu\text{V}/^\circ\text{C}$<br>$\mu\text{V}/^\circ\text{C}$ |
| $I_B$                    | Input Bias Current (Note 7)                   |                                                                                |        | 0.5           |                          | pA                                                           |
| $I_{OS}$                 | Input Offset Current (Note 7)                 |                                                                                |        | 1             |                          | pA                                                           |
| $i_n$                    | Input Noise Current Spectral Density          | $f \leq 100\text{Hz}$                                                          |        | 12            |                          | fA/ $\sqrt{\text{Hz}}$                                       |
| $e_n$                    | Input Noise Voltage Spectral Density          | $f \leq 100\text{Hz}$                                                          |        | 230           |                          | nV/ $\sqrt{\text{Hz}}$                                       |
| $e_{n\text{ P-P}}$       | Input Noise Voltage                           | DC to 10Hz                                                                     |        | 4.8           |                          | $\mu\text{V}_{\text{P-P}}$                                   |
| $C_{IN}$                 | Input Capacitance                             | Differential<br>Common Mode                                                    |        | 3.3<br>3.5    |                          | pF<br>pF                                                     |
| $V_{CMR}$                | Input Voltage Range                           | Guaranteed by CMRR                                                             | ●      | $(V^-) - 0.1$ | $(V^+) + 0.1$            | V                                                            |
| CMRR                     | Common Mode Rejection Ratio (Note 8)          | $V_{CM} = (V^-) - 0.1\text{V}$ to $(V^+) + 0.1\text{V}$<br>$R_L = 499\text{k}$ | ●      | 103<br>100    | 130                      | dB<br>dB                                                     |
| PSRR                     | Power Supply Rejection Ratio                  | $V_S = 1.7\text{V}$ to $5.25\text{V}$<br>$R_L = 499\text{k}$                   | ●      | 108<br>106    | 126                      | dB<br>dB                                                     |
| $A_{VOL}$                | Open Loop Gain                                | $V_{OUT} = (V^-) + 0.1\text{V}$ to $(V^+) - 0.1\text{V}$ , $R_L = 499\text{k}$ |        | 135           |                          | dB                                                           |
| $V_{OL}$                 | Output Voltage Swing Low ( $V_{OUT} - V^-$ )  | $R_L = 499\text{k}$<br>$R_L = 10\text{k}$                                      | ●      | 0.05<br>3     | 10<br>20                 | mV<br>mV<br>mV                                               |
| $V_{OH}$                 | Output Voltage Swing High ( $V^+ - V_{OUT}$ ) | $R_L = 499\text{k}$<br>$R_L = 10\text{k}$                                      | ●      | 0.1<br>4.5    | 10<br>50                 | mV<br>mV<br>mV                                               |
| $I_{SC}$                 | Output Short Circuit Current                  | Sourcing                                                                       | ●      | 5.8<br>5.6    | 7.5                      | mA<br>mA                                                     |
|                          |                                               | Sinking                                                                        | ●      | 10.4<br>5     | 13                       | mA<br>mA                                                     |

**ELECTRICAL CHARACTERISTICS** The ● denotes the specifications which apply over the full operating temperature range, otherwise specifications are at  $T_A = 25^\circ\text{C}$ . Unless otherwise noted,  $V_S = 1.8\text{V}$ ,  $V_{CM} = V_{OUT} = V_S/2$ ,  $V_{SHDN} = 1.8\text{V}$ ,  $R_L$  to  $V_S/2$ .

| SYMBOL                       | PARAMETER                                                               | CONDITIONS                                     | MIN | TYP  | MAX  | UNITS         |
|------------------------------|-------------------------------------------------------------------------|------------------------------------------------|-----|------|------|---------------|
| SR                           | Slew Rate                                                               | $A_V = +1$                                     |     | 3.5  |      | V/ms          |
| GBW                          | Gain Bandwidth Product                                                  | $R_L = 499\text{k}$                            |     | 20   |      | kHz           |
| $t_{ON}$                     | Power-Up Time                                                           |                                                |     | 2    |      | ms            |
| $f_C$                        | Internal Chopping Frequency                                             |                                                |     | 5    |      | kHz           |
| $V_S$                        | Supply Voltage Range                                                    | Guaranteed by PSRR                             | ●   | 1.7  | 5.25 | V             |
| $I_S$                        | Supply Current per Amplifier                                            | No Load                                        |     | 1.3  | 2    | $\mu\text{A}$ |
|                              |                                                                         | $-40^\circ\text{C}$ to $85^\circ\text{C}$      | ●   |      | 2.5  | $\mu\text{A}$ |
|                              |                                                                         | $-40^\circ\text{C}$ to $125^\circ\text{C}$     | ●   |      | 4    | $\mu\text{A}$ |
|                              |                                                                         | In Shutdown ( $\overline{\text{SHDN}} = V^-$ ) |     | 90   | 170  | nA            |
|                              |                                                                         | $-40^\circ\text{C}$ to $85^\circ\text{C}$      | ●   |      | 250  | nA            |
|                              |                                                                         | $-40^\circ\text{C}$ to $125^\circ\text{C}$     | ●   |      | 500  | nA            |
| $V_H$                        | $\overline{\text{SHDN}}$ Pin Threshold, Logic High (Referred to $V^-$ ) |                                                | ●   | 1.0  |      | V             |
| $V_L$                        | $\overline{\text{SHDN}}$ Pin Threshold, Logic Low (Referred to $V^-$ )  |                                                | ●   |      | 0.65 | V             |
| $I_{\overline{\text{SHDN}}}$ | $\overline{\text{SHDN}}$ Pin Current                                    | $V_{\overline{\text{SHDN}}} = 0\text{V}$       | ●   | -150 | -20  | nA            |

The ● denotes the specifications which apply over the full operating temperature range, otherwise specifications are at  $T_A = 25^\circ\text{C}$ . Unless otherwise noted,  $V_S = 5\text{V}$ ,  $V_{CM} = V_{OUT} = V_S/2$ ,  $V_{SHDN} = 5\text{V}$ ,  $R_L$  to  $V_S/2$ .

| SYMBOL                   | PARAMETER                                                                                                          | CONDITIONS                                                                              | MIN    | TYP           | MAX                      | UNITS                                                        |
|--------------------------|--------------------------------------------------------------------------------------------------------------------|-----------------------------------------------------------------------------------------|--------|---------------|--------------------------|--------------------------------------------------------------|
| $V_{OS}$                 | Input Offset Voltage (Note 6)                                                                                      | $V_S = 5.25\text{V}$                                                                    |        | 1             | $\pm 5$<br>$\pm 10$      | $\mu\text{V}$<br>$\mu\text{V}$                               |
| $\Delta V_{OS}/\Delta T$ | Input Offset Voltage Drift (Note 6)                                                                                | $-40^\circ\text{C}$ to $85^\circ\text{C}$<br>$-40^\circ\text{C}$ to $125^\circ\text{C}$ | ●<br>● |               | $\pm 0.02$<br>$\pm 0.05$ | $\mu\text{V}/^\circ\text{C}$<br>$\mu\text{V}/^\circ\text{C}$ |
| $I_B$                    | Input Bias Current                                                                                                 | $-40^\circ\text{C}$ to $85^\circ\text{C}$                                               | ●      | -3            | $\pm 20$                 | pA                                                           |
|                          |                                                                                                                    | $-40^\circ\text{C}$ to $125^\circ\text{C}$                                              | ●      |               | $\pm 30$                 | pA                                                           |
|                          |                                                                                                                    |                                                                                         |        |               | $\pm 100$                | pA                                                           |
| $I_{OS}$                 | Input Offset Current                                                                                               | $-40^\circ\text{C}$ to $85^\circ\text{C}$                                               | ●      | 1.5           | $\pm 20$                 | pA                                                           |
|                          |                                                                                                                    | $-40^\circ\text{C}$ to $125^\circ\text{C}$                                              | ●      |               | $\pm 30$                 | pA                                                           |
|                          |                                                                                                                    |                                                                                         |        |               | $\pm 100$                | pA                                                           |
| $i_n$                    | Input Noise Current Spectral Density                                                                               | $f \leq 100\text{Hz}$                                                                   |        | 12            |                          | fA/ $\sqrt{\text{Hz}}$                                       |
| $e_n$                    | Input Noise Voltage Spectral Density                                                                               | $f \leq 100\text{Hz}$                                                                   |        | 220           |                          | nV/ $\sqrt{\text{Hz}}$                                       |
| $e_{n\text{ P-P}}$       | Input Noise Voltage                                                                                                | DC to 10Hz                                                                              |        | 4.6           |                          | $\mu\text{V}_{\text{P-P}}$                                   |
| $C_{IN}$                 | Input Capacitance                                                                                                  | Differential                                                                            |        | 3.3           |                          | pF                                                           |
|                          |                                                                                                                    | Common Mode                                                                             |        | 3.5           |                          | pF                                                           |
| $V_{CMR}$                | Input Voltage Range                                                                                                | Guaranteed by CMRR                                                                      | ●      | $(V^-) - 0.1$ | $(V^+) + 0.1$            | V                                                            |
| CMRR                     | Common Mode Rejection Ratio                                                                                        | $V_{CM} = (V^-) - 0.1\text{V}$ to $(V^+) + 0.1\text{V}$                                 |        | 111           | 130                      | dB                                                           |
|                          |                                                                                                                    | $R_L = 499\text{k}$                                                                     | ●      | 108           |                          | dB                                                           |
| PSRR                     | Power Supply Rejection Ratio                                                                                       | $V_S = 1.7\text{V}$ to $5.25\text{V}$                                                   |        | 108           | 126                      | dB                                                           |
|                          |                                                                                                                    | $R_L = 499\text{k}$                                                                     | ●      | 106           |                          | dB                                                           |
| EMIRR                    | EMI Rejection Ratio<br>$V_{RF} = 100\text{mV}_{\text{PK}}$<br>$\text{EMIRR} = 20 \cdot \log(V_{RF}/\Delta V_{OS})$ | $f = 400\text{MHz}$                                                                     |        | 81            |                          | dB                                                           |
|                          |                                                                                                                    | $f = 900\text{MHz}$                                                                     |        | 102           |                          | dB                                                           |
|                          |                                                                                                                    | $f = 1800\text{MHz}$                                                                    |        | 114           |                          | dB                                                           |
|                          |                                                                                                                    | $f = 2400\text{MHz}$                                                                    |        | 100           |                          | dB                                                           |
| $A_{VOL}$                | Open Loop Gain                                                                                                     | $V_{OUT} = (V^-) + 0.1\text{V}$ to $(V^+) - 0.1\text{V}$ , $R_L = 499\text{k}$          |        | 112           | 140                      | dB                                                           |
|                          |                                                                                                                    |                                                                                         | ●      | 110           |                          | dB                                                           |

**ELECTRICAL CHARACTERISTICS** The ● denotes the specifications which apply over the full operating temperature range, otherwise specifications are at  $T_A = 25^\circ\text{C}$ . Unless otherwise noted,  $V_S = 5\text{V}$ ,  $V_{CM} = V_{OUT} = V_S/2$ ,  $V_{SHDN} = 5\text{V}$ ,  $R_L$  to  $V_S/2$ .

| SYMBOL     | PARAMETER                                                               | CONDITIONS                                     | MIN | TYP      | MAX      | UNITS         |
|------------|-------------------------------------------------------------------------|------------------------------------------------|-----|----------|----------|---------------|
| $V_{OL}$   | Output Voltage Swing Low ( $V_{OUT} - V^-$ )                            | $R_L = 499\text{k}$                            |     | 0.1      |          | mV            |
|            |                                                                         | $R_L = 10\text{k}$                             | ●   | 5.5      | 15<br>20 | mV<br>mV      |
| $V_{OH}$   | Output Voltage Swing High ( $V^+ - V_{OUT}$ )                           | $R_L = 499\text{k}$                            |     | 0.15     |          | mV            |
|            |                                                                         | $R_L = 10\text{k}$                             | ●   | 7        | 15<br>20 | mV<br>mV      |
| $I_{SC}$   | Output Short Circuit Current                                            | Sourcing                                       | ●   | 30<br>16 | 51       | mA<br>mA      |
|            |                                                                         | Sinking                                        | ●   | 20<br>5  | 48       | mA<br>mA      |
| SR         | Slew Rate                                                               | $A_V = +1$                                     |     | 3.5      |          | V/ms          |
| GBW        | Gain Bandwidth Product                                                  | $R_L = 499\text{k}$                            |     | 20       |          | kHz           |
| $t_{ON}$   | Power-Up Time                                                           |                                                |     | 2        |          | ms            |
| $f_C$      | Internal Chopping Frequency                                             |                                                |     | 5        |          | kHz           |
| $V_S$      | Supply Voltage Range                                                    | Guaranteed by PSRR                             | ●   | 1.7      | 5.25     | V             |
| $I_S$      | Supply Current per Amplifier                                            | No Load                                        | ●   | 1.4      | 2        | $\mu\text{A}$ |
|            |                                                                         | $-40^\circ\text{C}$ to $85^\circ\text{C}$      | ●   |          | 2.5      | $\mu\text{A}$ |
|            |                                                                         | $-40^\circ\text{C}$ to $125^\circ\text{C}$     | ●   |          | 4        | $\mu\text{A}$ |
|            |                                                                         | In Shutdown ( $\overline{\text{SHDN}} = V^-$ ) | ●   | 90       | 170      | nA            |
|            |                                                                         | $-40^\circ\text{C}$ to $85^\circ\text{C}$      | ●   |          | 250      | nA            |
|            |                                                                         | $-40^\circ\text{C}$ to $125^\circ\text{C}$     | ●   |          | 500      | nA            |
| $V_H$      | $\overline{\text{SHDN}}$ Pin Threshold, Logic High (Referred to $V^-$ ) |                                                | ●   | 1.8      |          | V             |
| $V_L$      | $\overline{\text{SHDN}}$ Pin Threshold, Logic Low (Referred to $V^-$ )  |                                                | ●   |          | 0.8      | V             |
| $I_{SHDN}$ | $\overline{\text{SHDN}}$ Pin Current                                    | $V_{SHDN} = 0\text{V}$                         | ●   | -150     | -20      | nA            |

**Note 1:** Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. Exposure to any Absolute Maximum Rating condition for extended periods may affect device reliability and lifetime.

**Note 2:** The inputs are protected by two series connected ESD protection diodes to each power supply. The input current should be limited to less than 10mA. The input voltage should not exceed 300mV beyond the power supply.

**Note 3:** A heat sink may be required to keep the junction temperature below the absolute maximum rating when the output is shorted indefinitely.

**Note 4:** The LTC2063I/LTC2064I/LTC2065I are guaranteed to meet specified performance from  $-40^\circ\text{C}$  to  $85^\circ\text{C}$ . The LTC2063H/LTC2064H/LTC2065H are guaranteed to meet specified performance from  $-40^\circ\text{C}$  to  $125^\circ\text{C}$ .

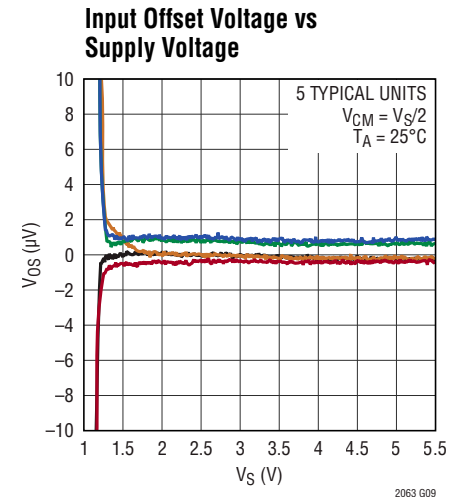
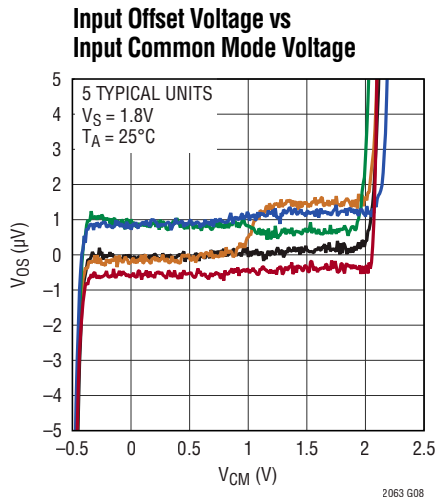
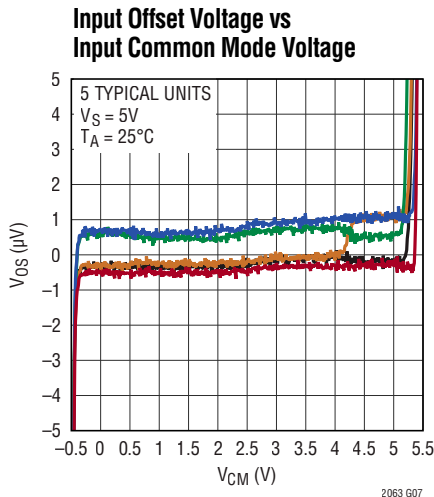
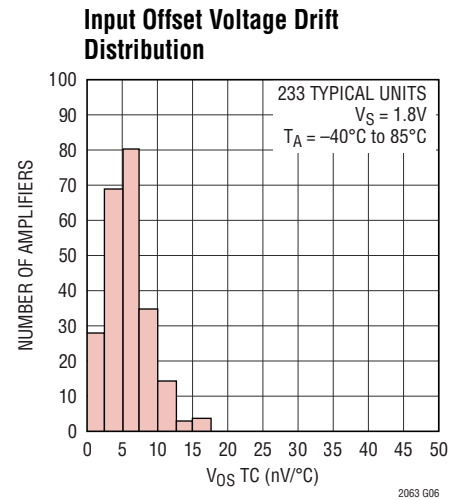
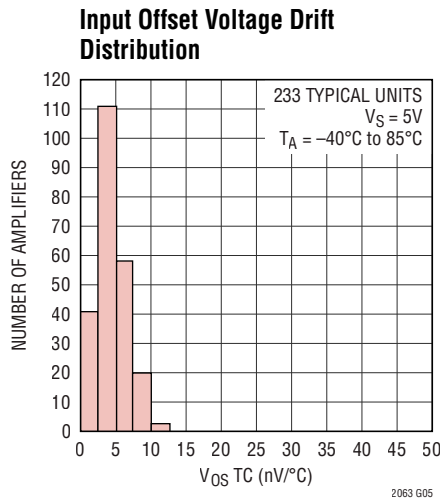
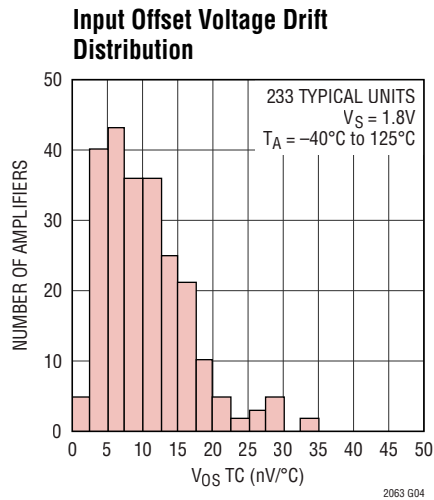
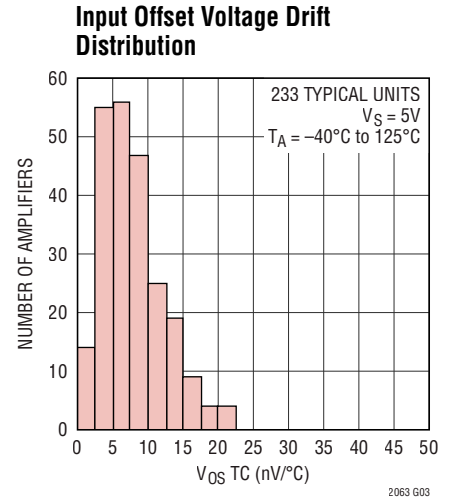
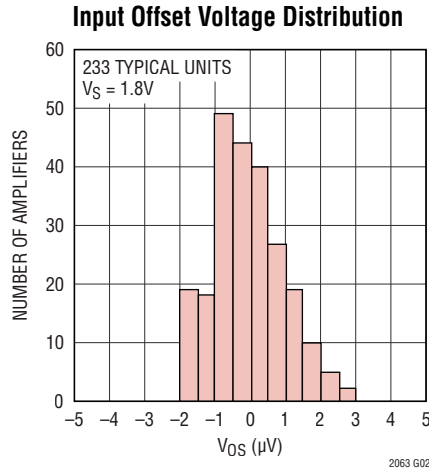
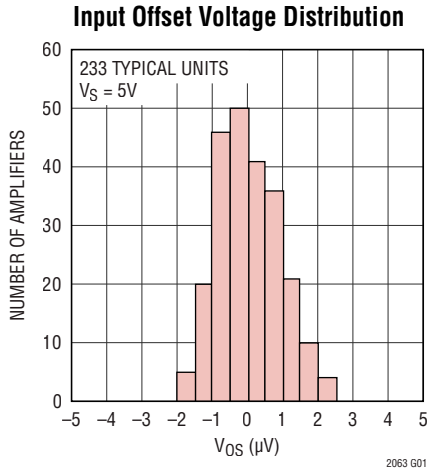
**Note 5:** Thermal resistance varies with the amount of PC board metal connected to the package. The specified values are for short traces connected to the leads.

**Note 6:** These parameters are guaranteed by design. Thermocouple effects preclude measurements of these voltage levels during automated testing.  $V_{OS}$  is measured to a limit determined by test equipment capability.

**Note 7:** Input bias current is only production tested at 5V. Input bias current at 1.8V is expected to meet or exceed 5V specifications.

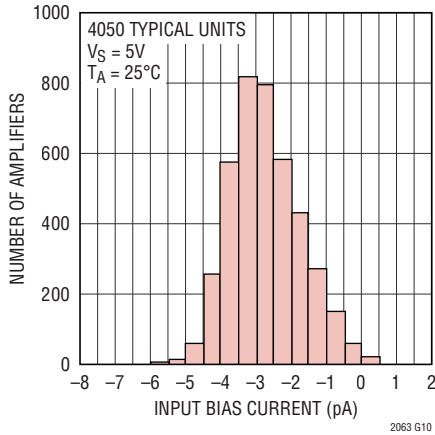
**Note 8:** Minimum specifications for these parameters are limited by noise and the capabilities of the automated test system.

## TYPICAL PERFORMANCE CHARACTERISTICS

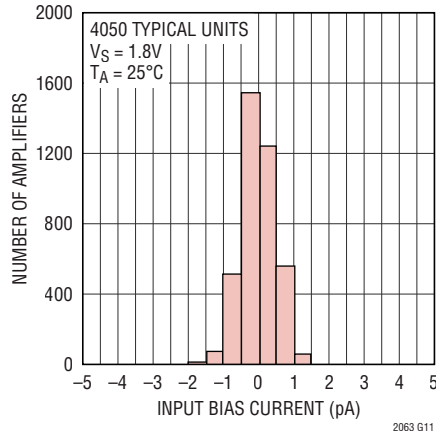


# TYPICAL PERFORMANCE CHARACTERISTICS

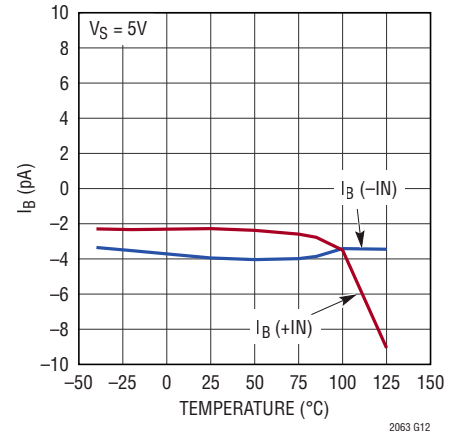
### Input Bias Current Distribution



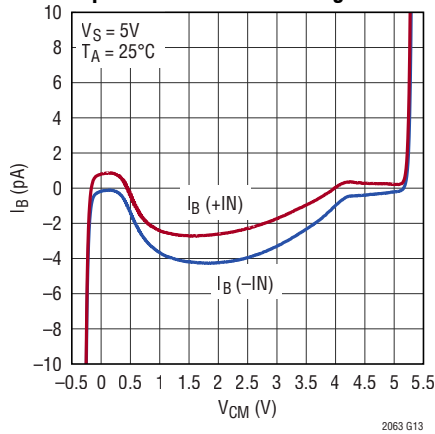
### Input Bias Current Distribution



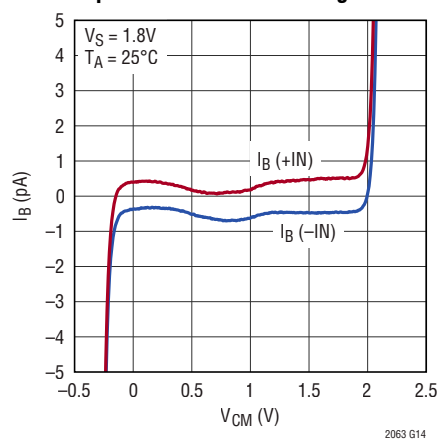
### Input Bias Current vs Temperature



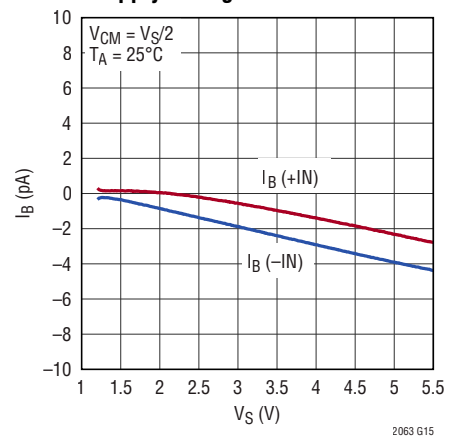
### Input Bias Current vs Input Common Mode Voltage



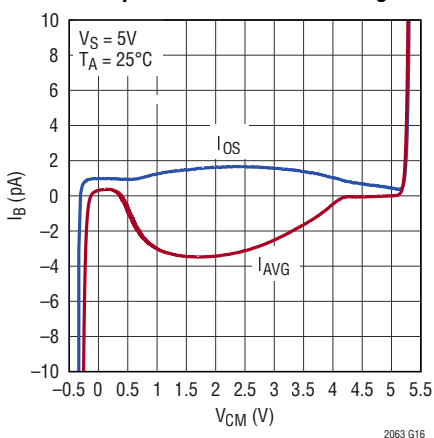
### Input Bias Current vs Input Common Mode Voltage



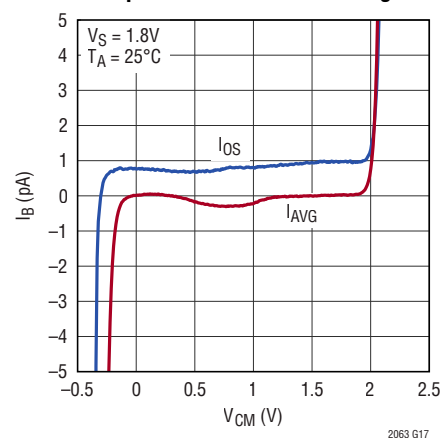
### Input Bias Current vs Supply Voltage



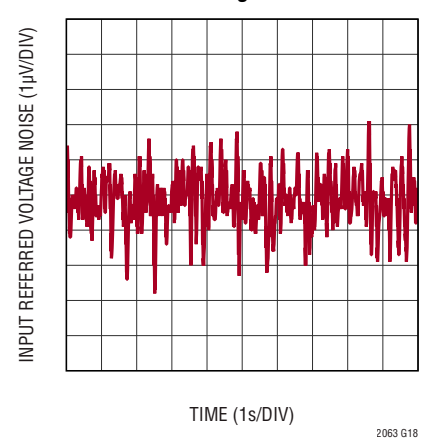
### Input Offset and Average Current vs Input Common Mode Voltage



### Input Offset and Average Current vs Input Common Mode Voltage

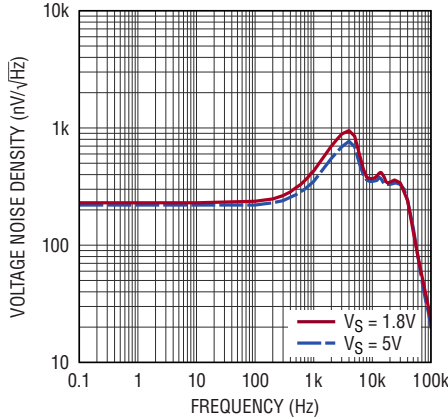


### DC to 10Hz Voltage Noise

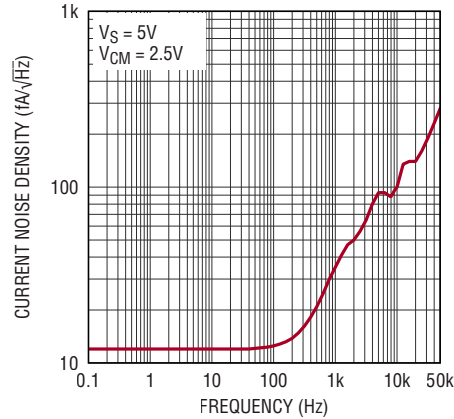


## TYPICAL PERFORMANCE CHARACTERISTICS

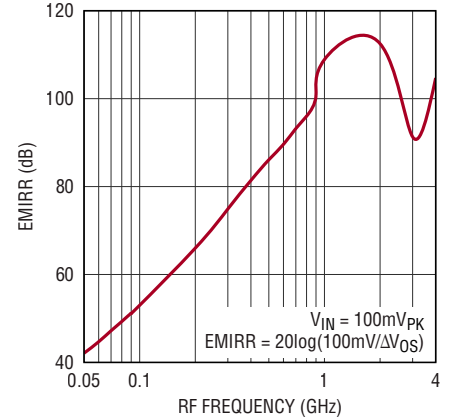
**Input Referred Voltage Noise Density**



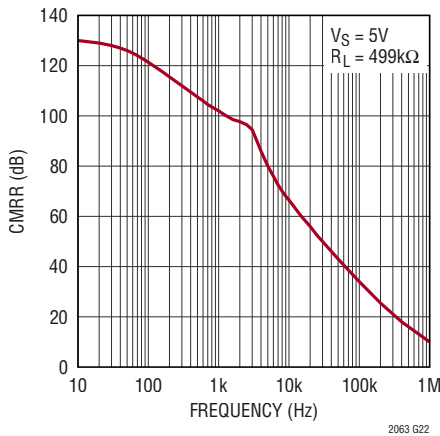
**Input Referred Current Noise Density**



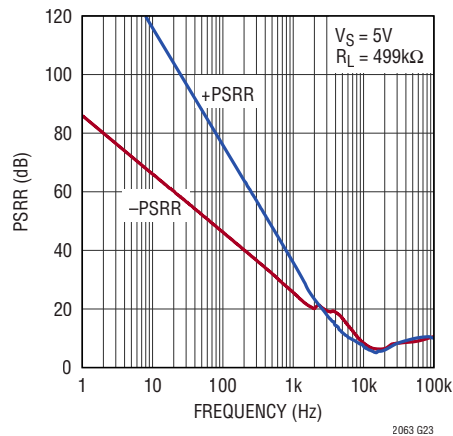
**EMI Rejection vs Frequency**



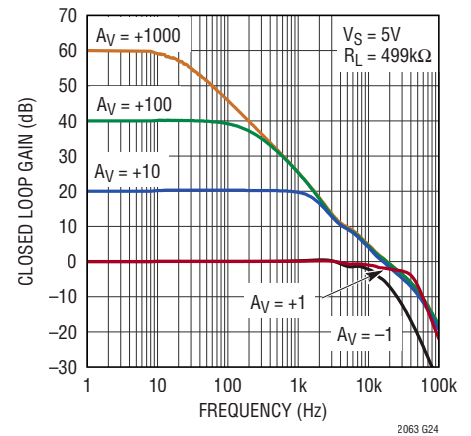
**Common Mode Rejection Ratio vs Frequency**



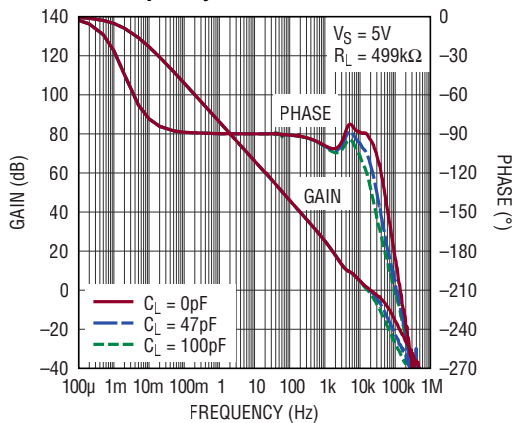
**Power Supply Rejection Ratio vs Frequency**



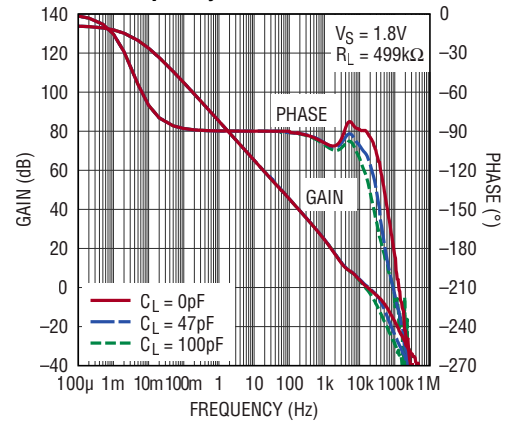
**Closed Loop Gain vs Frequency**



**Open Loop Gain and Phase vs Frequency**

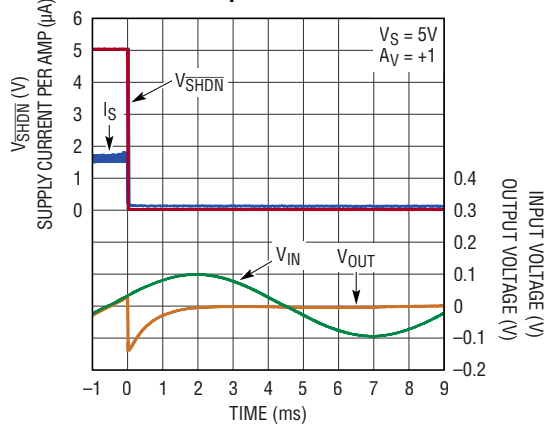


**Open Loop Gain and Phase vs Frequency**

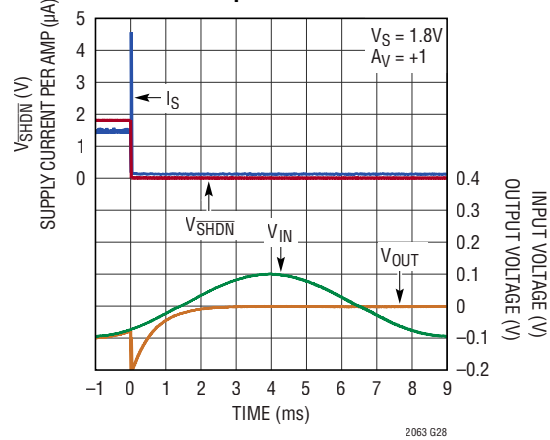


## TYPICAL PERFORMANCE CHARACTERISTICS

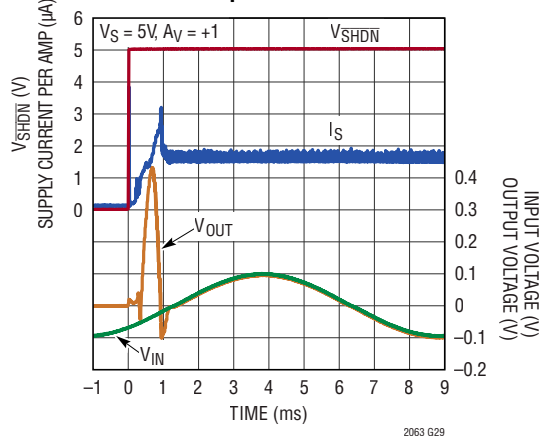
Shutdown Transient with Sinusoidal Input



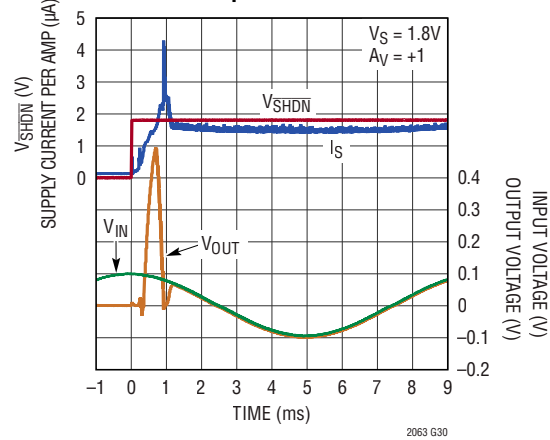
Shutdown Transient with Sinusoidal Input



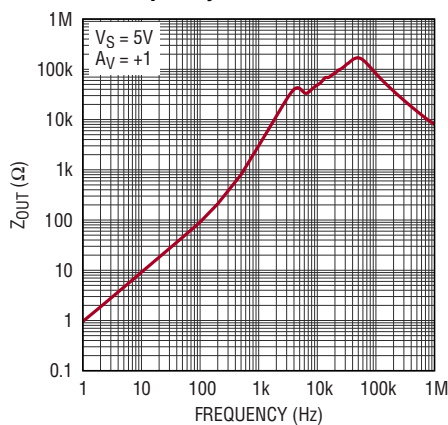
Enable Transient with Sinusoidal Input



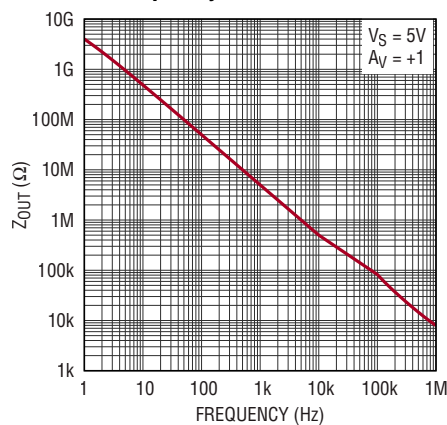
Enable Transient with Sinusoidal Input



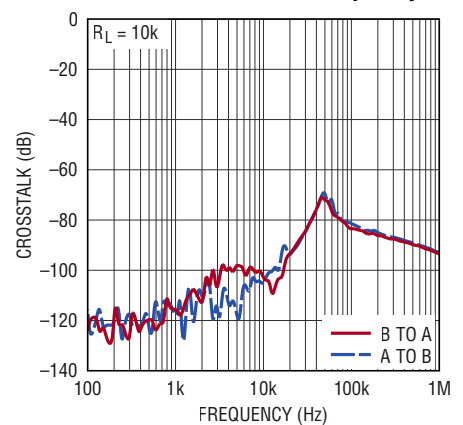
Closed Loop Output Impedance vs Frequency



Output Impedance in Shutdown vs Frequency



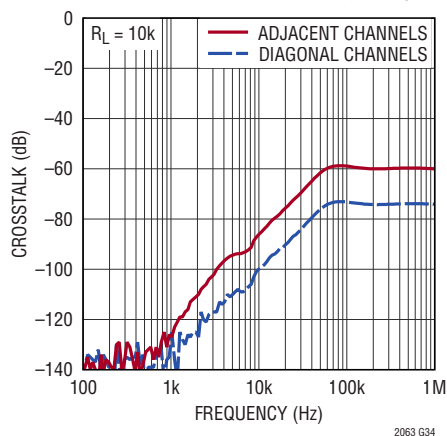
LTC2064 Crosstalk vs Frequency





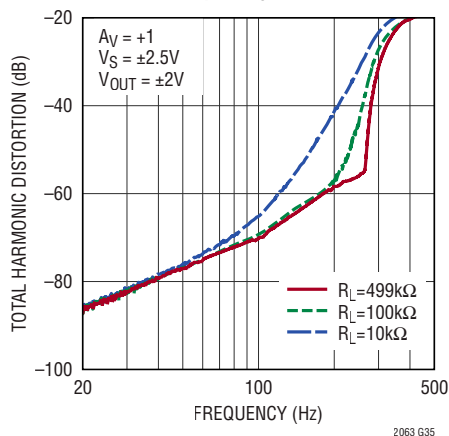
## TYPICAL PERFORMANCE CHARACTERISTICS

LTC2065 Crosstalk vs Frequency



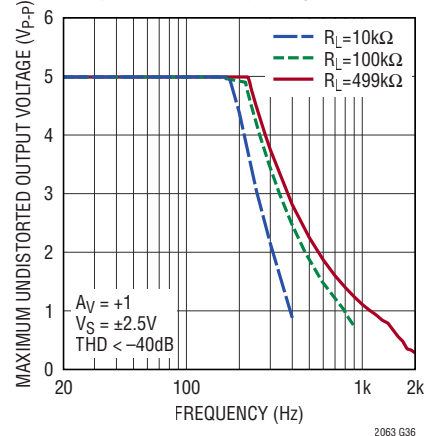
2063 G34

THD vs Frequency



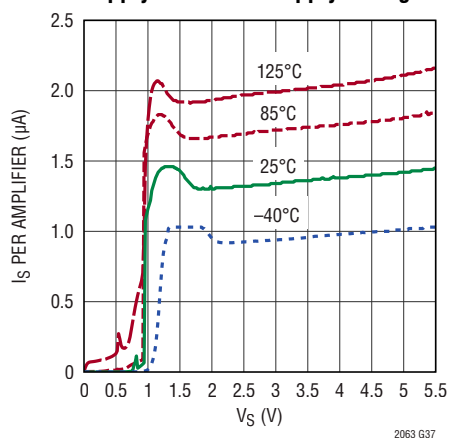
2063 G35

Maximum Undistorted Output Amplitude vs Frequency



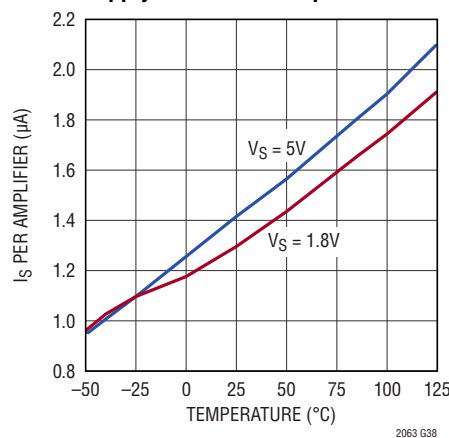
2063 G36

Supply Current vs Supply Voltage

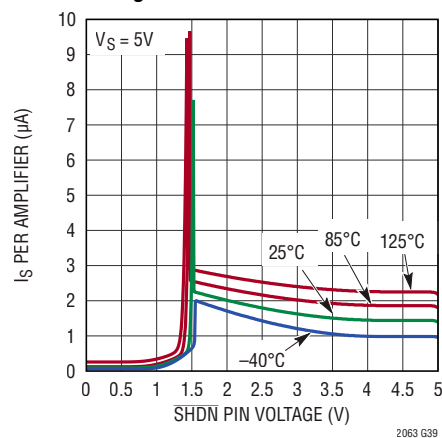


2063 G37

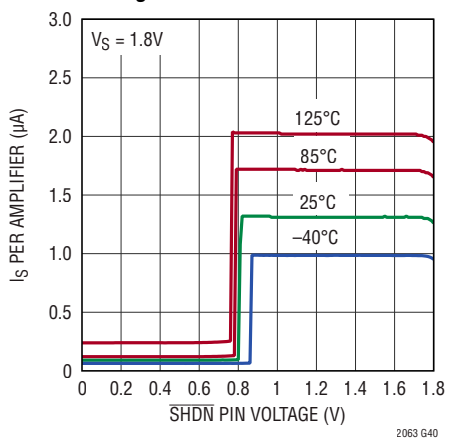
Supply Current vs Temperature



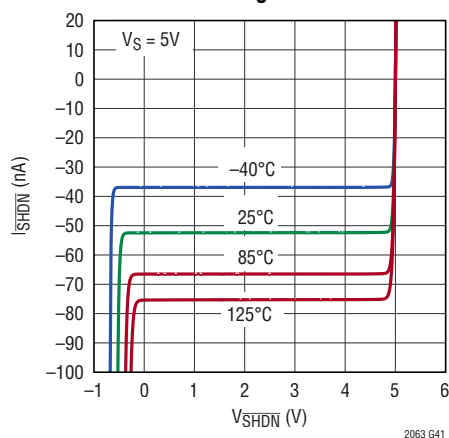
2063 G38

Supply Current vs  $\overline{SHDN}$  Pin Voltage

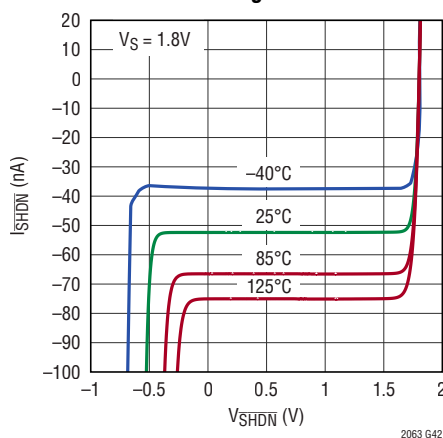
2063 G39

Supply Current vs  $\overline{SHDN}$  Pin Voltage

2063 G40

 $\overline{SHDN}$  Pin Pull-Up Current vs  $\overline{SHDN}$  Pin Voltage

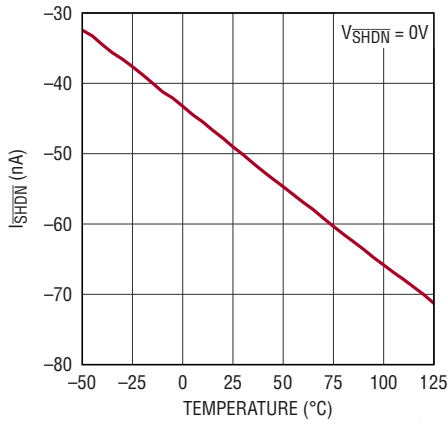
2063 G41

 $\overline{SHDN}$  Pin Pull-Up Current vs  $\overline{SHDN}$  Pin Voltage

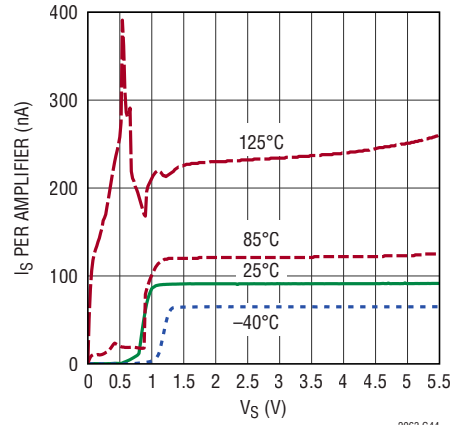
2063 G42

## TYPICAL PERFORMANCE CHARACTERISTICS

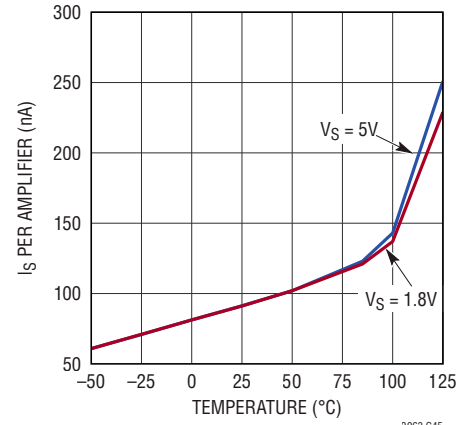
SHDN Pin Current vs Temperature



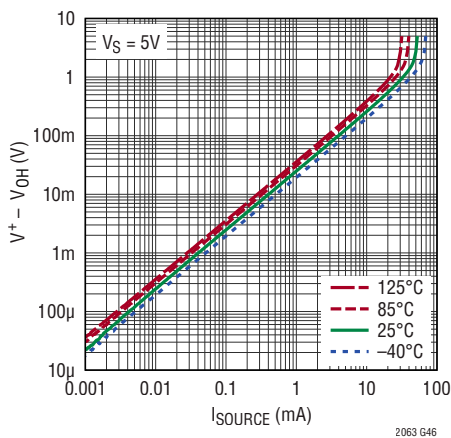
Shutdown Supply Current vs Supply Voltage



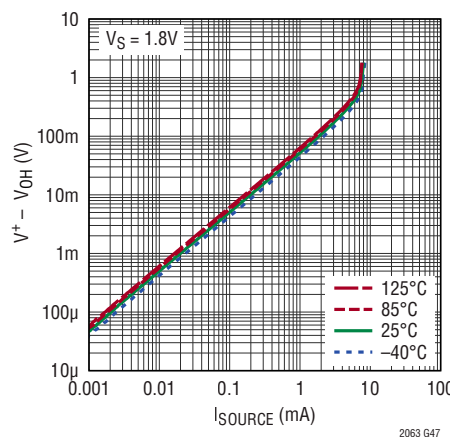
Shutdown Supply Current vs Temperature



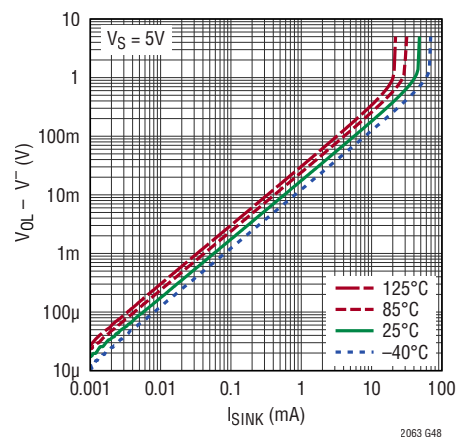
Output Voltage Swing High vs Load Current



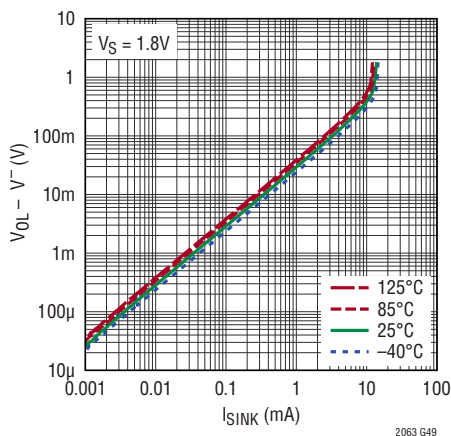
Output Voltage Swing High vs Load Current



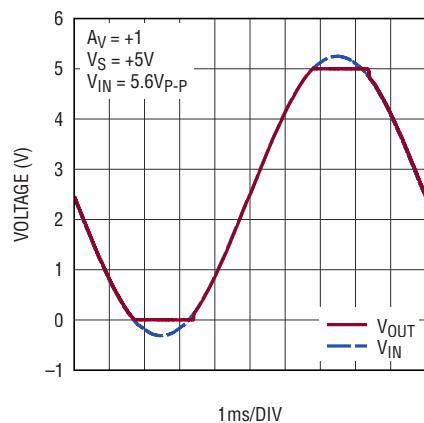
Output Voltage Swing Low vs Load Current



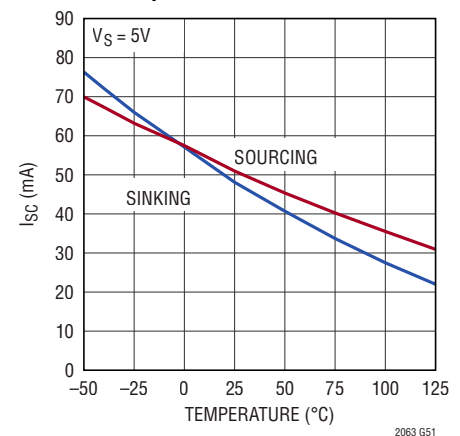
Output Voltage Swing Low vs Load Current



No Phase Reversal

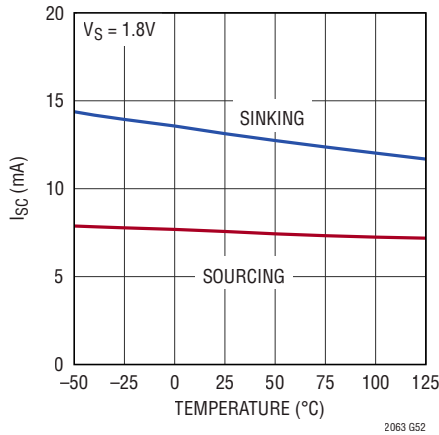


Output Short Circuit Current vs Temperature

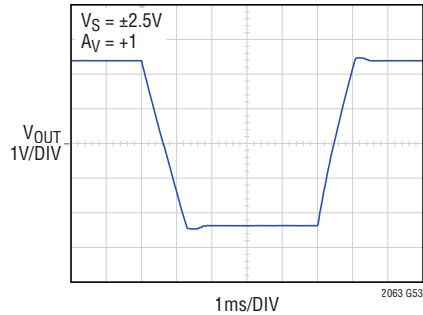


## TYPICAL PERFORMANCE CHARACTERISTICS

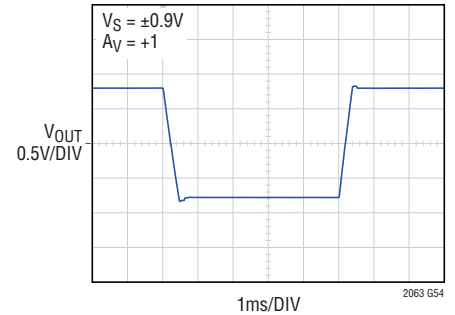
**Output Short Circuit Current vs Temperature**



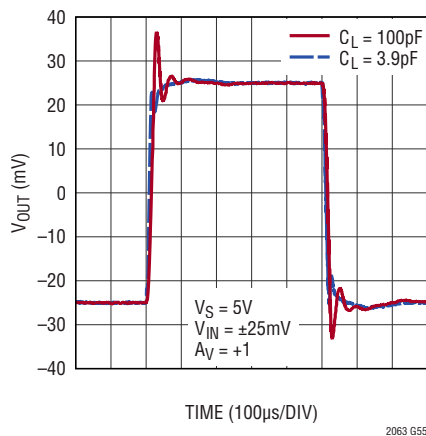
**Large Signal Response**



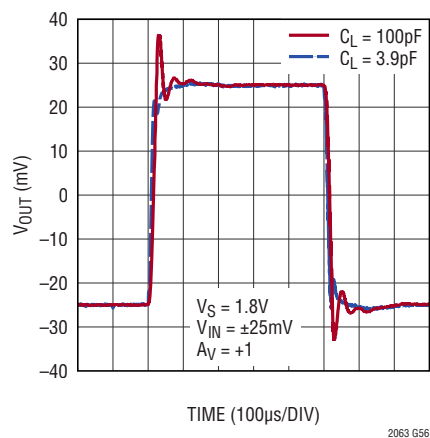
**Large Signal Response**



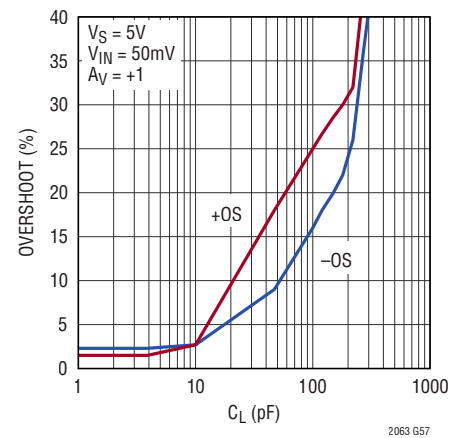
**Small Signal Response**



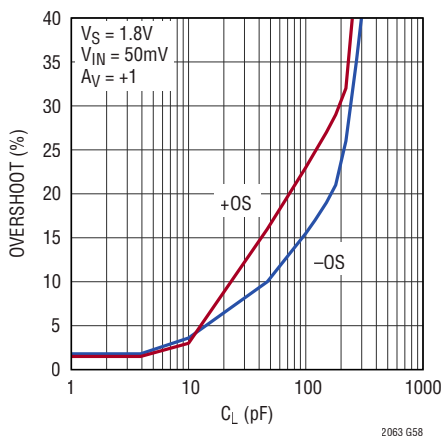
**Small Signal Response**



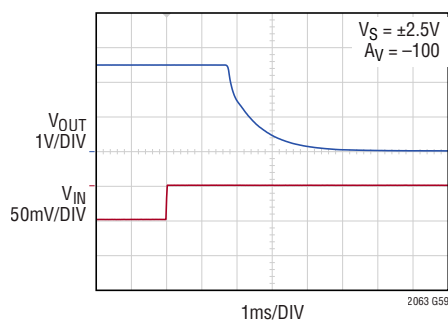
**Small Signal Overshoot vs Load Capacitance**



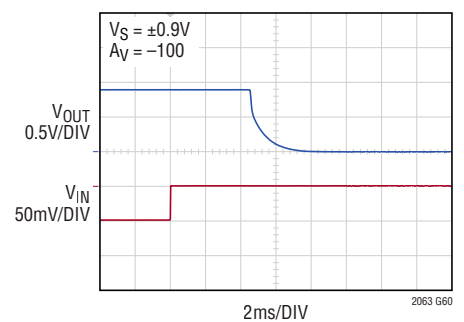
**Small Signal Overshoot vs Load Capacitance**



**Positive Output Overload Recovery**

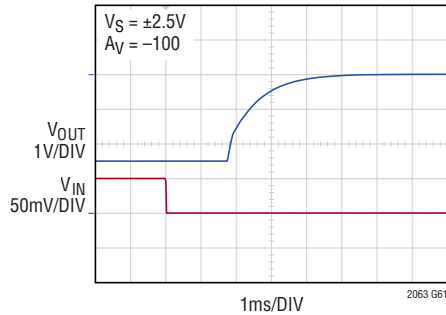


**Positive Output Overload Recovery**

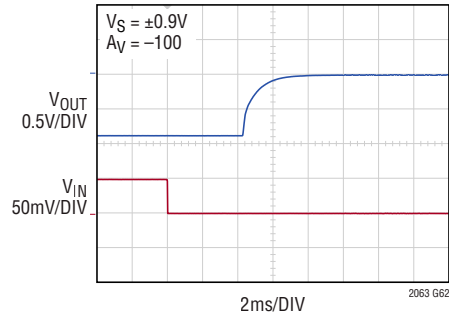


## TYPICAL PERFORMANCE CHARACTERISTICS

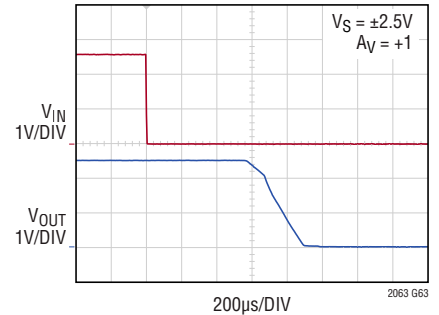
Negative Output Overload Recovery



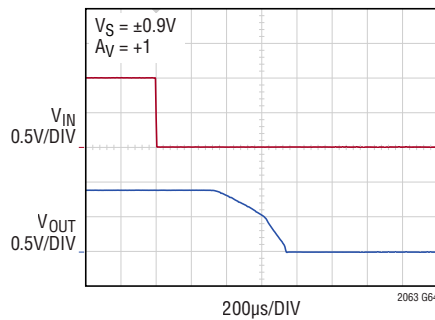
Negative Output Overload Recovery



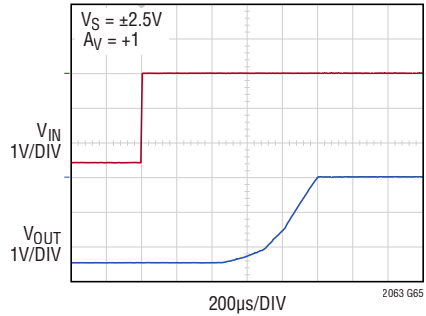
Positive Input Overload Recovery



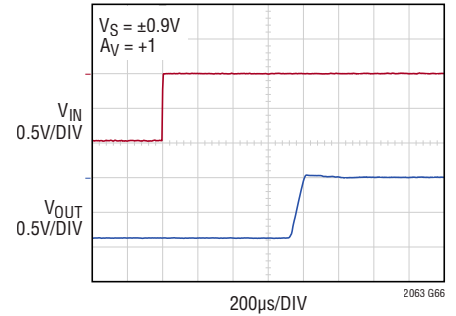
Positive Input Overload Recovery



Negative Input Overload Recovery



Negative Input Overload Recovery



## PIN FUNCTIONS

**OUT:** Amplifier Output

**-IN:** Inverting Amplifier Input

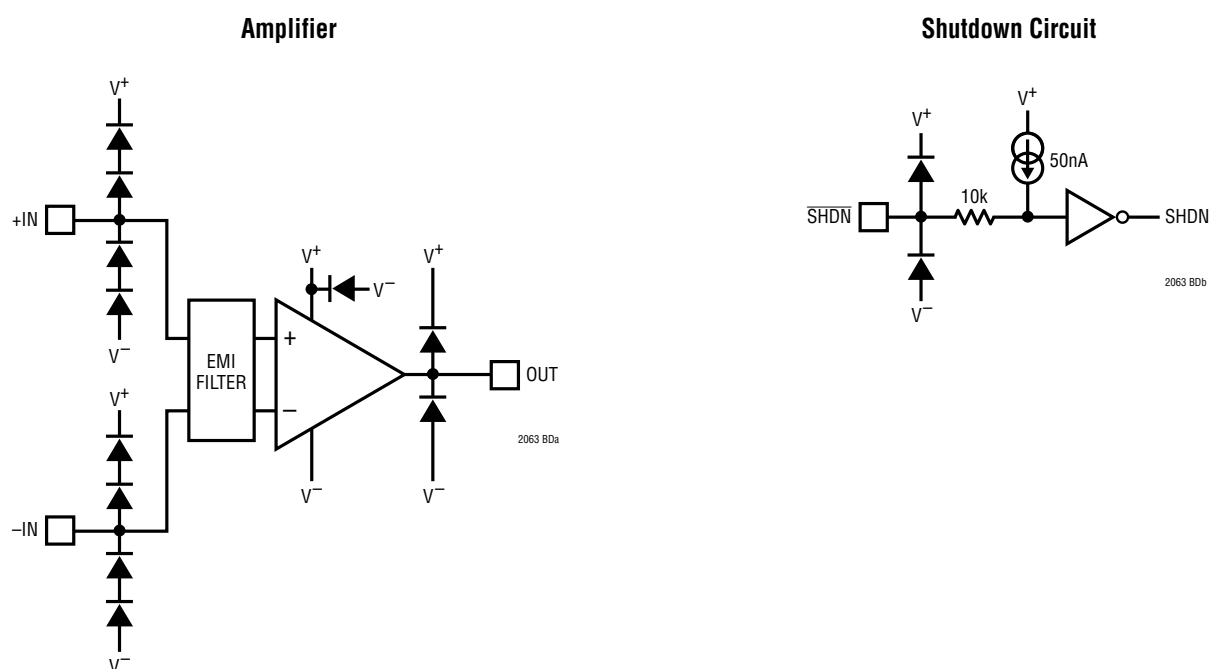
**+IN:** Noninverting Amplifier Input

**V<sup>+</sup>:** Positive Power Supply. A bypass capacitor should be used between supply pins and ground.

**V<sup>-</sup>:** Negative Power Supply. A bypass capacitor should be used between supply pins and ground.

**$\overline{\text{SHDN}}$ :** Shutdown Control Pin. The  $\overline{\text{SHDN}}$  pin threshold is referenced to V<sup>-</sup>. If tied to V<sup>+</sup>, the part is enabled. If tied to V<sup>-</sup>, the part is disabled and draws less than 170nA of supply current per amplifier. It is recommended to not float this pin.

## BLOCK DIAGRAM



## APPLICATIONS INFORMATION

### Using the LTC2063/LTC2064/LTC2065

The LTC2063/LTC2064/LTC2065 are single, dual and quad zero-drift operational amplifiers with the open-loop voltage gain and bandwidth characteristics of a conventional operational amplifier. Advanced circuit techniques allow the LTC2063/LTC2064/LTC2065 to operate continuously through its entire bandwidth while self-calibrating unwanted errors.

### Input Voltage Noise

Zero-drift amplifiers like the LTC2063/LTC2064/LTC2065 achieve low input offset voltage and  $1/f$  noise by heterodyning DC and flicker noise to higher frequencies. In early zero-drift amplifiers, this process resulted in idle tones at the self-calibration frequency, often referred to as the chopping frequency. These artifacts made early zero-drift amplifiers difficult to use. The advanced circuit techniques used by the LTC2063/LTC2064/LTC2065 suppress these spurious artifacts, allowing for trouble-free use.

### Input Current Noise

For applications with high source and feedback impedances, input current noise can be a significant contributor to total output noise. For this reason, it is important to consider noise current interaction with circuit elements placed at the amplifier's inputs.

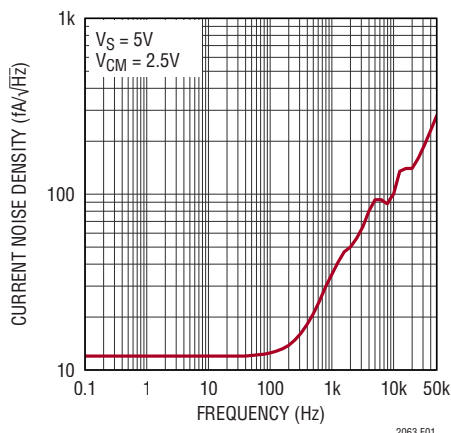


Figure 1. Input Current Noise Spectrum

The current noise spectrum of the LTC2063/LTC2064/LTC2065 is shown in Figure 1. Low input current noise is achieved through the use of MOSFET input devices and self-calibration techniques to eliminate  $1/f$  current noise. As with all zero-drift amplifiers, there is an increase in current noise at the offset-nulling frequency. This phenomenon is discussed in the Input Bias Current and Clock Feedthrough section.

Input current noise also rises with frequency due to capacitive coupling of MOSFET channel thermal noise.

### Input Bias Current and Clock Feedthrough

The input bias current of zero-drift amplifiers has different characteristics than that of a traditional operational amplifier. The specified input bias current is the DC average of transient currents which conduct due to the input stage's switching circuitry. In addition to this, junction leakages can contribute additional input bias current at elevated temperatures. Through careful design and the use of an innovative boot-strap circuit the input bias current of the LTC2063/LTC2064/LTC2065 does not exceed 20pA at room and 100pA over the full temperature range. This minimizes bias current induced errors even in high impedance circuits.

Transient switching currents at the input interact with source and feedback impedances producing error voltages which are indistinguishable from a valid input signal. The resulting error voltages are amplified by the amplifier's closed-loop gain, which acts as a filter, attenuating frequency components above the circuit bandwidth. This phenomenon is known as clock feedthrough and is present in all zero-drift amplifiers. Understanding the cause and effect of clock feedthrough is important when using zero-drift amplifiers.

For zero-drift amplifiers, clock feedthrough is proportional to source and feedback impedances, as well as the magnitude of the transient currents. These transient currents have been minimized in the LTC2063/LTC2064/LTC2065

## APPLICATIONS INFORMATION

to allow use with high source and feedback impedances. Many circuit designs require high feedback impedances to minimize power consumption and/or require a sensor which is intrinsically high impedance. In these cases, a capacitor can be used, either at the input or across the feedback resistor, to limit the bandwidth of the closed-loop system. Doing so will effectively filter out the clock feedthrough signal.

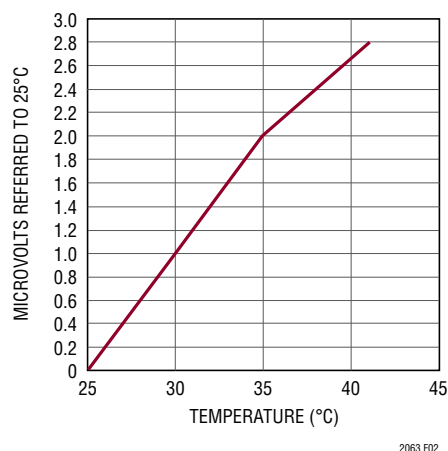
### Thermocouple Effects

In order to achieve accuracy on the microvolt level, thermocouple effects must be considered. Any connection of dissimilar metals forms a thermoelectric junction and generates a small temperature-dependent voltage. Also known as the Seebeck Effect, these thermal EMFs can be the dominant error source in low-drift circuits.

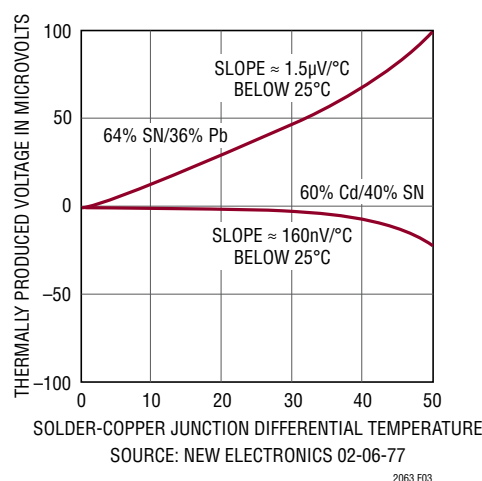
Connectors, switches, relay contacts, sockets, resistors, and solder are all candidates for significant thermal EMF generation. Even junctions of copper wire from different manufacturers can generate thermal EMFs of 200nV/°C, which significantly exceeds the maximum drift specification of the LTC2063/LTC2064/LTC2065. Figures 2 and 3 illustrate the potential magnitude of these voltages and their sensitivity to temperature.

In order to minimize thermocouple-induced errors, attention must be given to circuit board layout and component selection. It is good practice to minimize the number of junctions in the amplifier's input signal path and avoid connectors, sockets, switches, and relays whenever possible. If such components are required, they should be selected for low thermal EMF characteristics. Furthermore, the number, type, and layout of junctions should be matched for both inputs with respect to thermal gradients on the circuit board. Doing so may involve deliberately introducing dummy junctions to offset unavoidable junctions.

Air currents can also lead to thermal gradients and cause significant noise in measurement systems. It is important to prevent airflow across sensitive circuits. Doing so will often reduce thermocouple noise substantially. A summary of techniques can be found in Figure 4.



**Figure 2. Thermal EMF Generated by Two Copper Wires from Different Manufacturers**

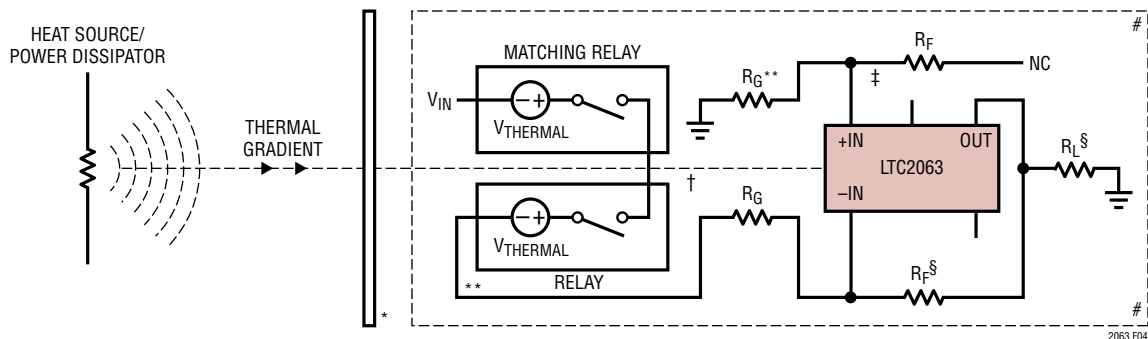


**Figure 3. Solder-Copper Thermal EMFs**

### Leakage Effects

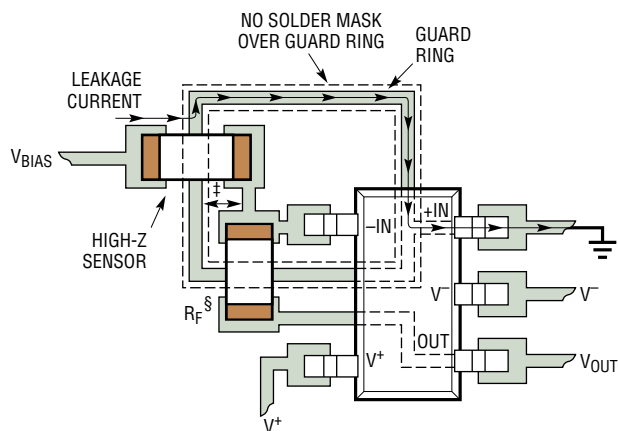
Leakage currents into high impedance signal nodes can easily degrade measurement accuracy of sub-nanoamp signals. High voltage and high temperature applications are especially susceptible to these issues. Quality insulation materials should be used, and insulating surfaces should be cleaned to remove fluxes and other residues. For humid environments, surface coating may be necessary to provide a moisture barrier.

## APPLICATIONS INFORMATION

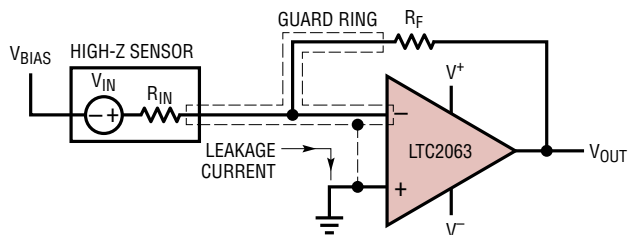


- \* CUT SLOTS IN PCB FOR THERMAL ISOLATION.  
 \*\* INTRODUCE DUMMY JUNCTIONS AND COMPONENTS TO OFFSET UNAVOIDABLE JUNCTIONS OR CANCEL THERMAL EMFs.  
 † ALIGN INPUTS SYMMETRICALLY WITH RESPECT TO THERMAL GRADIENTS.  
 ‡ INTRODUCE DUMMY TRACES AND COMPONENTS FOR SYMMETRICAL THERMAL HEAT SINKING.  
 § LOADS AND FEEDBACK CAN DISSIPATE POWER AND GENERATE THERMAL GRADIENTS. BE AWARE OF THEIR THERMAL EFFECTS.  
 # COVER CIRCUIT TO PREVENT AIR CURRENTS FROM CREATING THERMAL GRADIENTS.

Figure 4. Techniques for Minimizing Thermocouple-Induced Errors



- ‡ NO LEAKAGE CURRENT,  $V_{-IN} = V_{+IN}$   
 § AVOID DISSIPATING SIGNIFICANT AMOUNTS OF POWER IN THIS RESISTOR. IT WILL GENERATE THERMAL GRADIENTS WITH RESPECT TO THE INPUT PINS AND LEAD TO THERMOCOUPLE-INDUCED ERROR. THERMALLY ISOLATE OR ALIGN WITH INPUTS IF RESISTOR WILL CAUSE HEATING.



LEAKAGE CURRENT IS ABSORBED BY GROUND INSTEAD OF CAUSING A MEASUREMENT ERROR.

Figure 5. Example Layout of Inverting Amplifier with Leakage Guard Ring



## APPLICATIONS INFORMATION

Board leakage can be minimized by encircling the input connections with a guard ring operated at a potential very close to that of the inputs. The ring must be tied to a low impedance node. For inverting configurations, the guard ring should be tied to the potential of the positive input (+IN). For noninverting configurations, the guard ring should be tied to the potential of the negative input (–IN). In order for this technique to be effective, the guard ring must not be covered by solder mask. Ringing both sides of the printed circuit board may be required. See Figure 5 for an example of proper layout.

### Shutdown Mode

The LTC2063 in the SC70 package, the LTC2064 in the DFN package and the LTC2065 in the QFN package, feature a shutdown mode for low-power applications. In the OFF state, each amplifier draws less than 170nA of supply current and the outputs present a high impedance to external circuitry.

Shutdown operation is accomplished by tying  $\overline{\text{SHDN}}$  below  $V_L$ . If the shutdown feature is not required, it is recommended that  $\overline{\text{SHDN}}$  be tied to  $V^+$ . A current source pulls the  $\overline{\text{SHDN}}$  pin high to automatically keep the amplifier in the ON state when the pin is floated, however this may not be reliable at elevated temperatures due to board leakage (see  $\overline{\text{SHDN}}$  Circuit Block Diagram). For operation in noisy environments, a capacitor between  $\overline{\text{SHDN}}$  and  $V^+$  is recommended to prevent noise from changing the shutdown state. When there is a danger of  $\overline{\text{SHDN}}$  being pulled beyond the supply rails, resistance in series with the  $\overline{\text{SHDN}}$  pin is recommended to limit the resulting current.

### Start-Up Characteristics

Micropower op amps are often not micropower during start-up, which can cause problems when used on low current supplies. Large transient currents can conduct during power-up until the internal bias nodes settle to their final values. A large amount of current can be drawn from the supplies during this transient, which can sustain for several milliseconds in the case of a micropower part.

In the worst case, there may not be enough supply current available to take the system up to nominal voltages. In other cases, this transient power-up current will lead to added power loss in duty-cycled applications.

A way to quantify the transient current loss is to integrate the supply current during power-up to examine the total charge loss. If there were no additional transient current, the integrated supply current would appear as a smooth, straight line with a slope equal to the DC supply current of the part. Any deviation from a straight line indicates additional transient current that is drawn from the supply. The LTC2063/LTC2064/LTC2065 have been designed to minimize this charge loss during power-up so that power can be conserved in duty-cycled applications. Figure 6 shows the integrated supply current (i.e. charge) of the LTC2063 during power-up. Likewise, Figure 7 shows the charge loss due to enabling and disabling the part via the  $\overline{\text{SHDN}}$  pin.

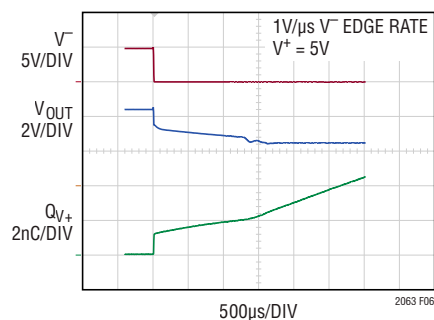


Figure 6. LTC2063 Charge Loss During Power-Up

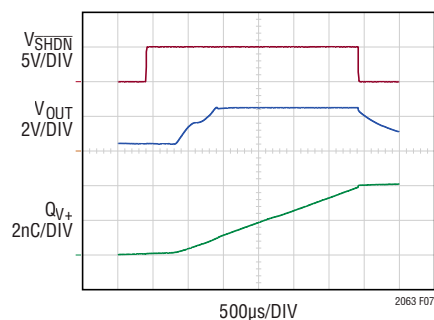


Figure 7. LTC2063 Charge Loss Due to Enabling and Disabling via  $\overline{\text{SHDN}}$  Pin

## APPLICATIONS INFORMATION

There are benefits when the  $\overline{\text{SHDN}}$  pin is used to disable and enable the part in duty-cycled applications, rather than powering down the external supply voltage ( $V^+$ ). Powering up and powering down the external supply will tend to waste charge due to charging and discharging the external decoupling capacitors. For these power-cycled applications, a relay or MOS device can be located after the decoupling capacitors to alleviate this, however there are drawbacks to this approach. The LTC2063 draws an initial charge of approximately 2nC when powered up. This recurring charge loss is unavoidable in power-cycled applications. Additionally, if the supply ramp rate exceeds  $0.4\text{V}/\mu\text{s}$ , an internal transient ESD clamp will trigger, conducting additional current from  $V^+$  to  $V^-$ . This will waste charge and can make insignificant any gain that may have been expected by power-cycling the supply. Figure 8 shows the charge loss at power-up.

The shutdown pin can be used to overcome these limitations in duty-cycled applications. The typical charge loss transitioning into and out of shutdown is only 1nC. Since the supply is not transitioned, the external decoupling capacitors do not draw charge from the supply.

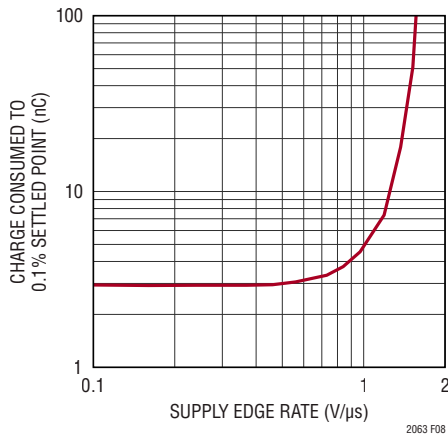


Figure 8. LTC2063 Power-Up Charge vs Supply Edge Rate

### Gas Sensor

This low power precision gas sensor circuit operates in an oxygen level range of 0% to 30%, with a nominal output of 1V in normal atmospheric oxygen concentrations (20.9%) when the gas sensor has been fully initialized. Total active power consumption is less than  $2.1\mu\text{A}$  on a single rail supply.

Since this gas sensor produces  $100\mu\text{A}$  in a normal oxygen environment and requires a  $100\Omega$  load resistor, the resulting input signal is typically around 10mV. The LTC2063's rail-to-rail input means no additional DC level shifting is necessary, all the way down to very low oxygen concentrations.

Due to the extremely low input offset voltage of the LTC2063, which is  $1\mu\text{V}$  typically and  $5\mu\text{V}$  maximum, it is possible to gain up the mV-scale input signal substantially without introducing significant error. In the configuration shown in Figure 9, with a noninverting gain of  $101\text{V}/\text{V}$ , the worst-case input offset results in a maximum of 0.5mV offset on the 1V output, or 0.05% error.

Although the  $100\text{k}\Omega$  resistor in series with the gas sensor does not strictly have the same precision requirement as the  $10\text{M}\Omega$  and  $100\text{k}\Omega$  resistors that set the gain, it is important to use a similar resistor at both input terminals. This helps to minimize additional offset voltage at the inputs due to thermocouple effects, hence the similar 0.1% precision requirement.

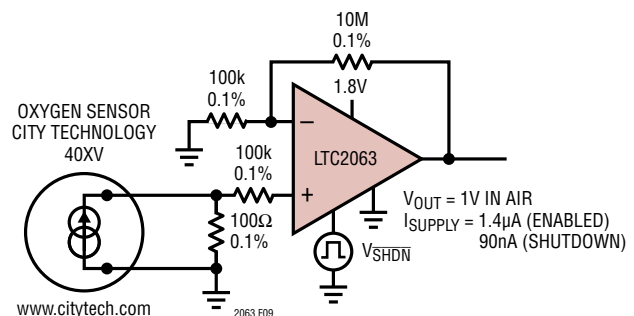


Figure 9. Micropower Precision Oxygen Sensor

## APPLICATIONS INFORMATION

### RTD Sensor

This low power platinum resistance temperature detector (RTD) sensor circuit draws only 35 $\mu$ A total supply current on a minimum 2.6V rail, and is accurate to within  $\pm 1^\circ\text{C}$  at room temperature, including all error intrinsic to the Vishay PTS Class F0.3 Variant RTD. It covers the temperature range from  $-40^\circ\text{C}$  to  $85^\circ\text{C}$  in 10mV/ $^\circ\text{C}$  increments and produces an output of 1V at nominal room temperature of  $25^\circ\text{C}$ .

The LTC2063's extremely low typical offset of 1 $\mu$ V and typical input bias current of 3pA allows for the use of a very low excitation current in the RTD. Thus, self-heating is negligible, improving accuracy.

The LT5400-3, B-grade, is used to provide a  $\pm 0.025\%$  matched resistor network that is effectively a precision 131:1 voltage divider. This precision divider forms one half of a bridge circuit, with the 0.1% 110k $\Omega$  and RTD in the other branch. Note that the 110k $\Omega$ 's precision requirement is to ensure matching with the RTD. The 11k $\Omega$  R2 serves to provide a DC offset for the entire bridge so

that the output is 1V at room temperature. Since bridge imbalances can lead to error, it is recommended to minimize the length of the leads connecting the RTD to reduce additional lead resistance.

The LT6656-2.048 reference helps create a known excitation current in the RTD at each temperature of operation, and also acts as a supply for the LTC2063, all while using less than 1 $\mu$ A itself. The LT6656 can accept input voltages anywhere between 2.6V and 18V, allowing for flexibility in selection of supply voltage while maintaining a fixed output range. The LT6656 reference can easily source the 35 $\mu$ A required to run the entire circuit, thanks to the LTC2063's 2 $\mu$ A maximum supply current and ability to handle microvolt signals produced by the RTD under low excitation current.

Care should be taken to minimize thermocouple effects by preventing significant thermal gradients between the two op amp inputs. It is also important to choose feedback and series resistors that are low-tempco to minimize error due to drift over the entire temperature range.

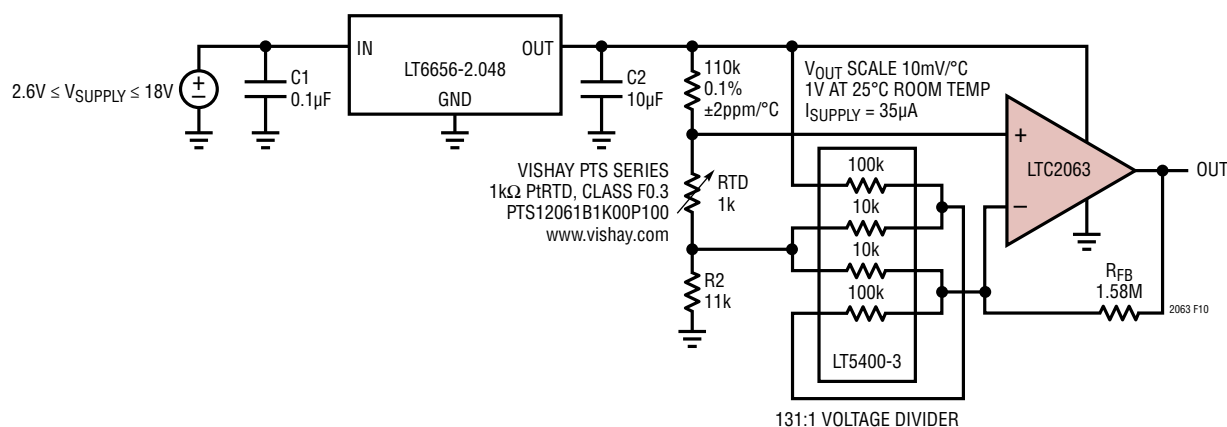


Figure 10. RTD Sensor

## APPLICATIONS INFORMATION

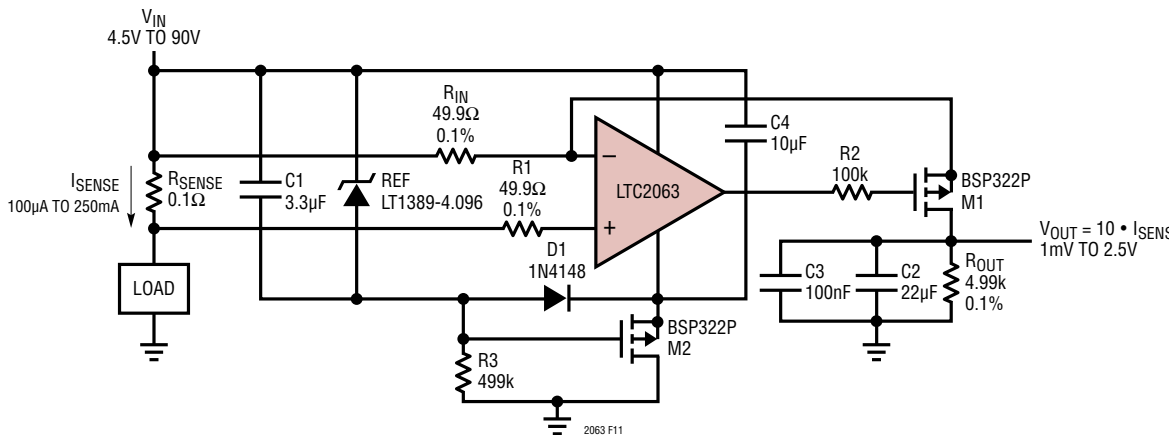


Figure 11. High Side Current Sense

**90V High Side Current Sense**

This micropower precision LTC2063 high side current sense circuit measures currents from 100µA to 250mA over a 4.5V to 90V input voltage range.

The output of this circuit is:

$$V_{OUT} = \frac{R_{OUT} \cdot R_{SHUNT}}{R_{IN}} I_{SENSE} = 500 \cdot I_{SENSE}$$

The LTC2063's low typical input offset voltage of 1µV and low input bias current of 3pA contribute output errors that are much smaller than the error due to precision limitations of the resistors used. Thus, output accuracy

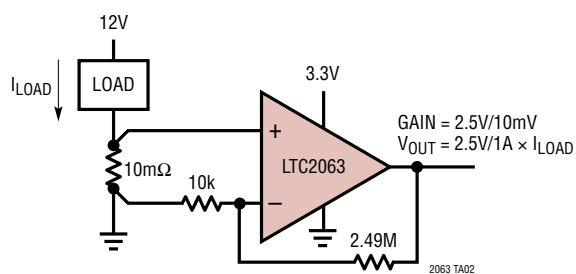
is mainly set by the accuracy of the resistors  $R_{SENSE}$ ,  $R_{IN}$ , and  $R_{OUT}$ .

The LT1389-4.096V reference, along with the bootstrap circuit composed of M2, R3, and D1, establishes a very low power isolated 3V rail that protects the LTC2063 from reaching its absolute maximum voltage of 5.5V while allowing for much higher input voltages.

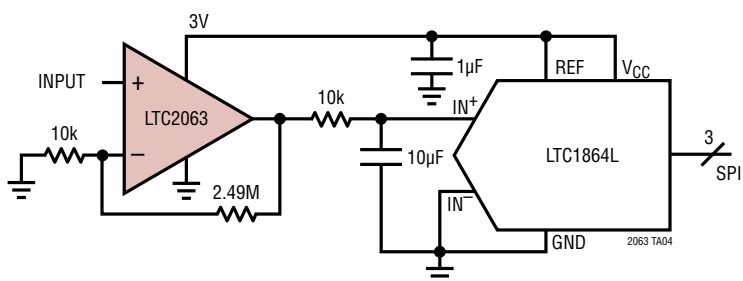
Since the LTC2063's gain-bandwidth product is 20kHz, it is recommended to use this circuit to measure signals that are 2kHz or slower. Note that the output filter as drawn will limit the frequency to 1.5Hz, which optimizes for lowest noise. If this output filter bandwidth is too narrow, removing C2 leads to an output filter with 318Hz bandwidth, created by C3 and  $R_{OUT}$ .

## TYPICAL APPLICATIONS

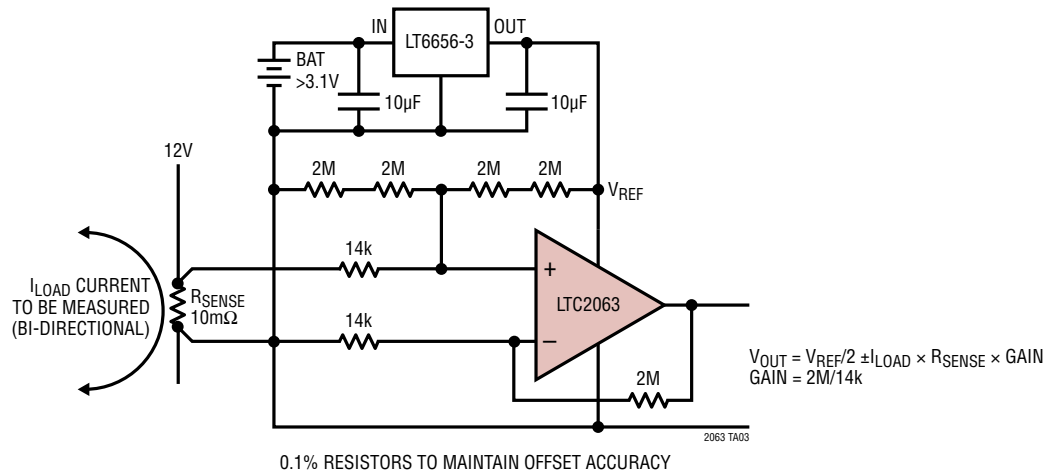
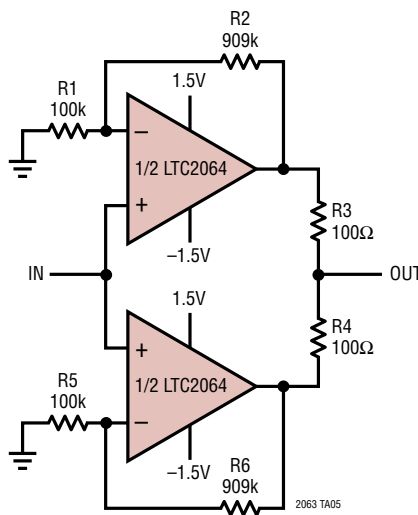
### Precision Micropower Low Side Current Sense



### Micropower 16-Bit Data Acquisition

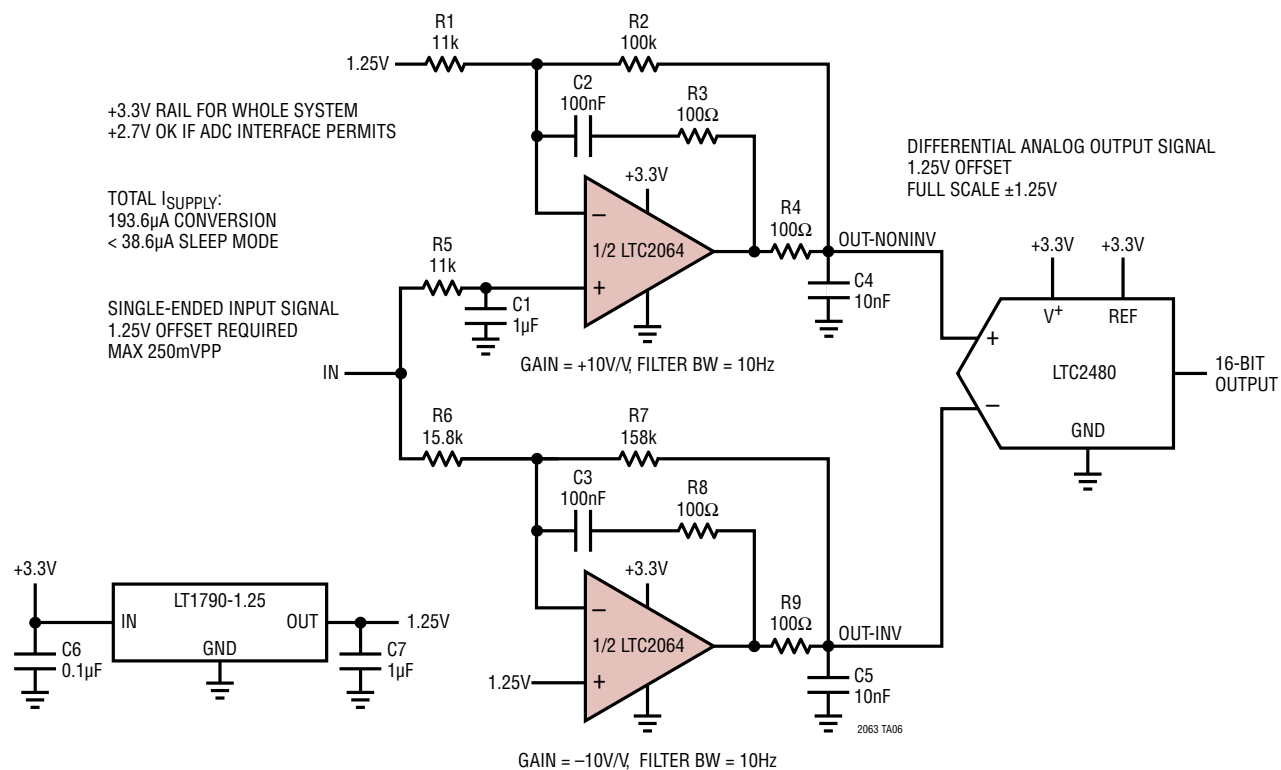


## TYPICAL APPLICATIONS

Parallel LTC2064 Amplifiers to Reduce Noise by  $\sqrt{2}$ 

## TYPICAL APPLICATIONS

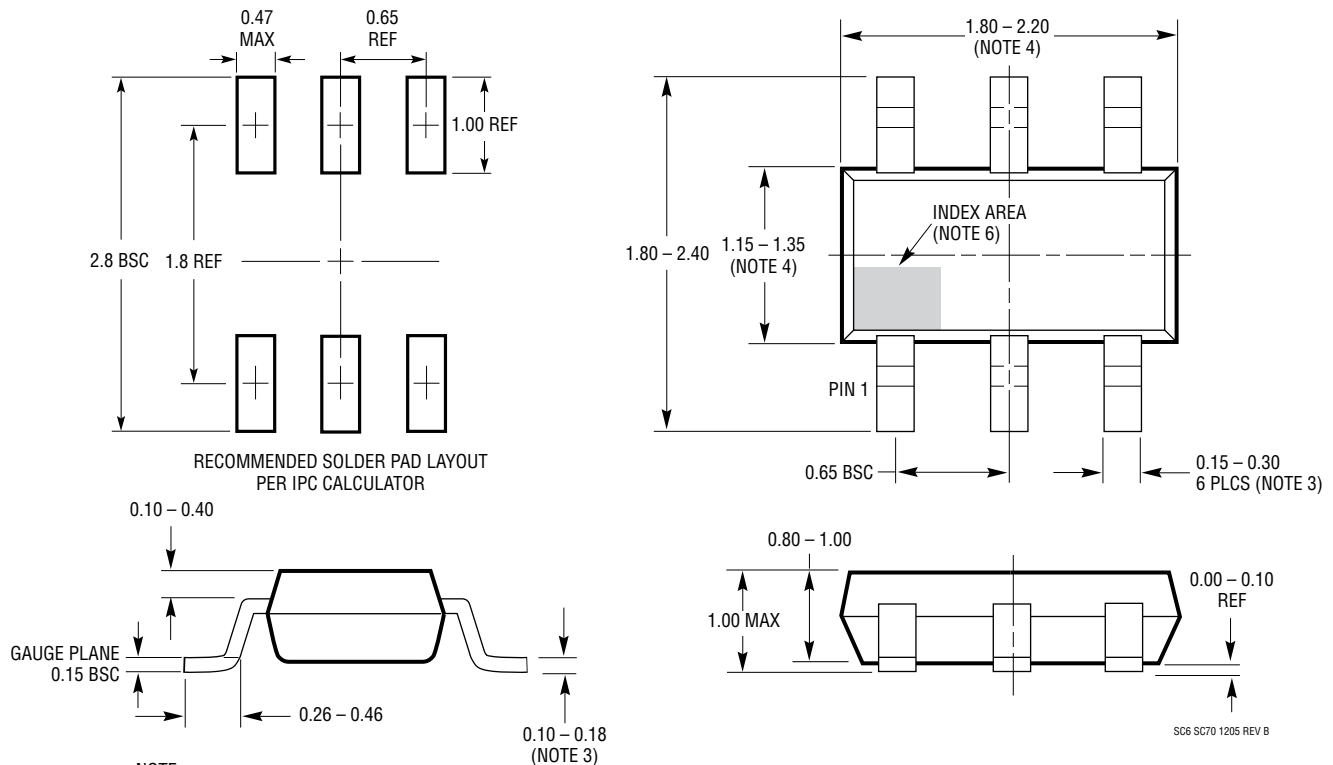
## Micropower 16-Bit Data Acquisition with Single-to-Differential Input Driver



# PACKAGE DESCRIPTION

## SC6 Package 6-Lead Plastic SC70

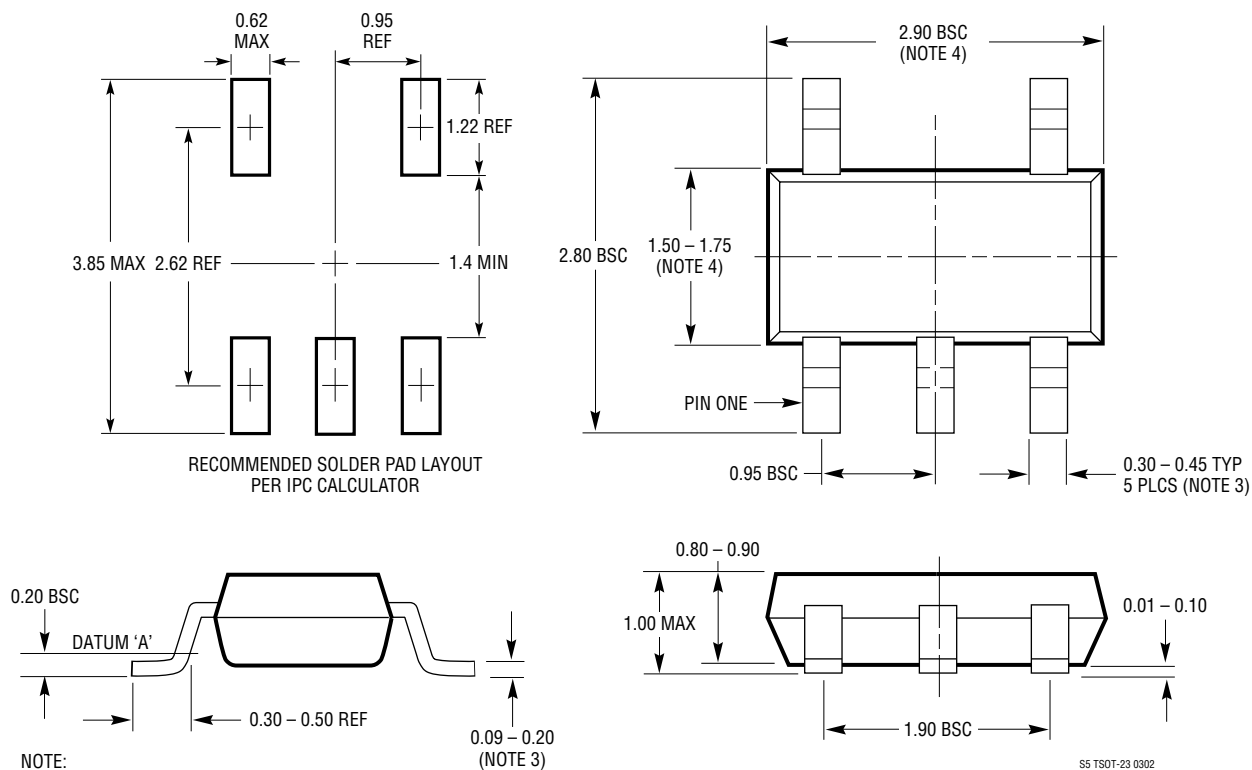
(Reference LTC DWG # 05-08-1638 Rev B)





## PACKAGE DESCRIPTION

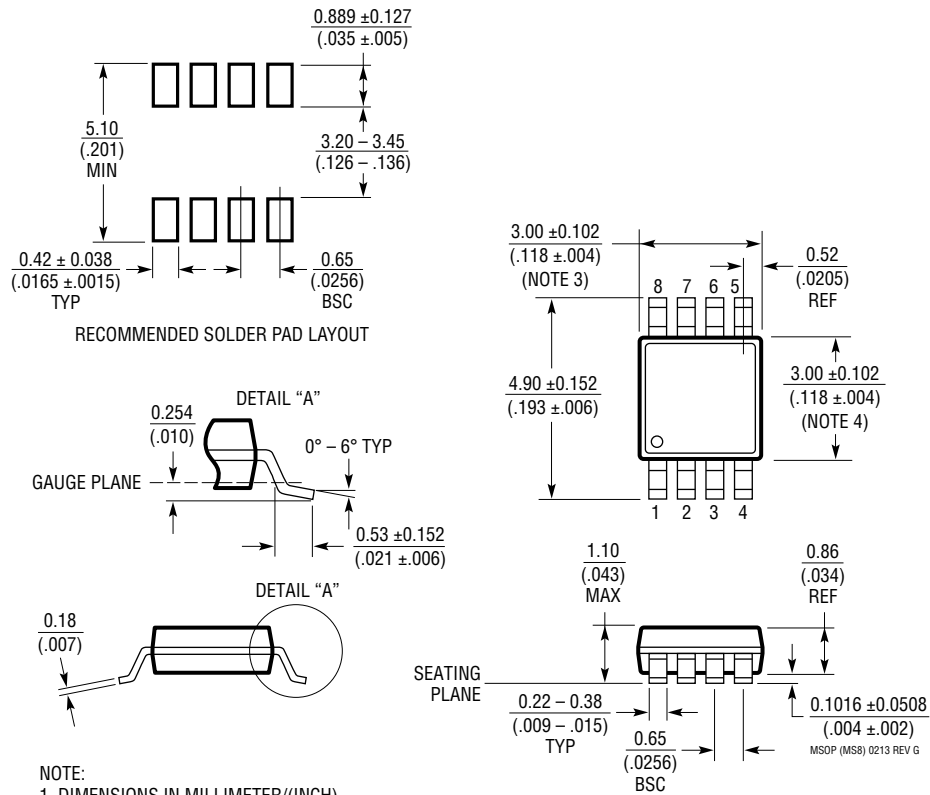
### S5 Package 5-Lead Plastic TSOT-23 (Reference LTC DWG # 05-08-1635)



# PACKAGE DESCRIPTION

## MS8 Package 8-Lead Plastic MSOP

(Reference LTC DWG # 05-08-1660 Rev G)



## NOTE:

1. DIMENSIONS IN MILLIMETER/(INCH)
2. DRAWING NOT TO SCALE
3. DIMENSION DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS.  
MOLD FLASH, PROTRUSIONS OR GATE BURRS SHALL NOT EXCEED 0.152mm (.006") PER SIDE
4. DIMENSION DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSIONS.  
INTERLEAD FLASH OR PROTRUSIONS SHALL NOT EXCEED 0.152mm (.006") PER SIDE
5. LEAD COPLANARITY (BOTTOM OF LEADS AFTER FORMING) SHALL BE 0.102mm (.004") MAX

Diagram illustrating the top view of a package with dimensions and package outline:

- Overall width:  $3.55 \pm 0.05$
- Distance from top edge to top of package body:  $2.15 \pm 0.05$
- Distance from top edge to top of package body (2 SIDES):  $1.65 \pm 0.05$
- Distance from top edge to top of package body (2 SIDES):  $0.70 \pm 0.05$
- Distance from top edge to top of package body (2 SIDES):  $0.25 \pm 0.05$
- Distance from top edge to top of package body (2 SIDES):  $0.50$  BSC
- Distance from top edge to top of package body (2 SIDES):  $2.38 \pm 0.05$  (2 SIDES)
- Package Outline is indicated by a dashed line.

**RECOMMENDED SOLDER PAD PITCH AND DIMENSIONS**

The figure illustrates the recommended solder pad pitch and dimensions for the component, showing three views:

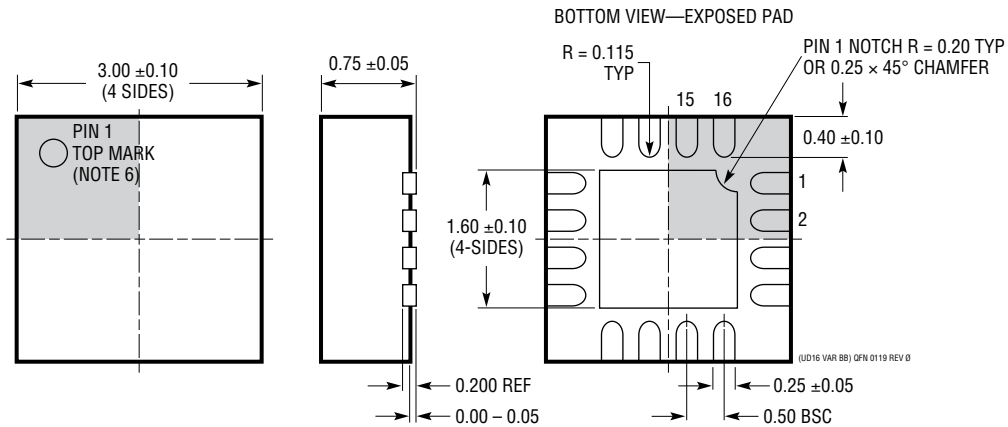
- Top View:** Shows the overall dimensions of the package, including the 3.00 ± 0.10 (4 SIDES) width and height, and the location of the PIN 1 TOP MARK (SEE NOTE 6).
- Bottom View—EXPOSED PAD:** Provides detailed dimensions for the exposed pad area, including the 0.75 ± 0.05 length, 0.25 ± 0.05 width, 0.50 BSC (Basic Spacing) dimension, and the 2.38 ± 0.10 (2 SIDES) distance between pads.
- Side Cross-Section View:** Illustrates the profile of the solder pad, showing the 0.40 ± 0.10 thickness, the 0.125 typical radius (R = 0.125 TYP), and the PIN 1 NOTCH with a radius of R = 0.20 OR 0.35 × 45° CHAMFER.

(DD) DFN REV C 0310

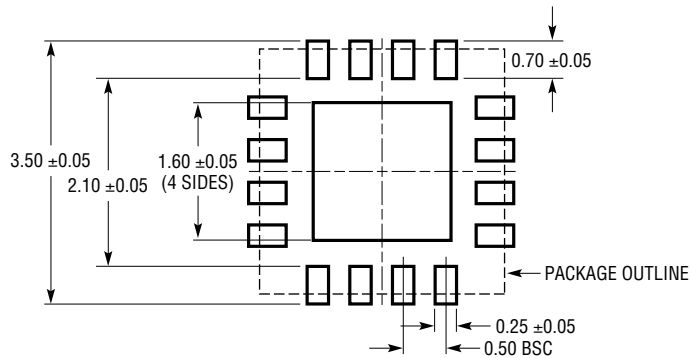
1. DRAWING TO BE MADE A JEDEC PACKAGE OUTLINE MO-229 VARIATION OF (WEED-2).  
CHECK THE LTC WEBSITE DATA SHEET FOR CURRENT STATUS OF VARIATION ASSIGNMENT
2. DRAWING NOT TO SCALE
3. ALL DIMENSIONS ARE IN MILLIMETERS
4. DIMENSIONS OF EXPOSED PAD ON BOTTOM OF PACKAGE DO NOT INCLUDE  
MOLD FLASH. MOLD FLASH, IF PRESENT, SHALL NOT EXCEED 0.15mm ON ANY SIDE
5. EXPOSED PAD SHALL BE SOLDER PLATED
6. SHADED AREA IS ONLY A REFERENCE FOR PIN 1 LOCATION ON THE  
TOP AND BOTTOM OF PACKAGE

## PACKAGE DESCRIPTION

**UD Package**  
**16-Lead Plastic QFN (3mm × 3mm)**  
 (Reference LTC DWG # 05-08-1782 Rev 0)  
**Exposed Pad Variation BB**



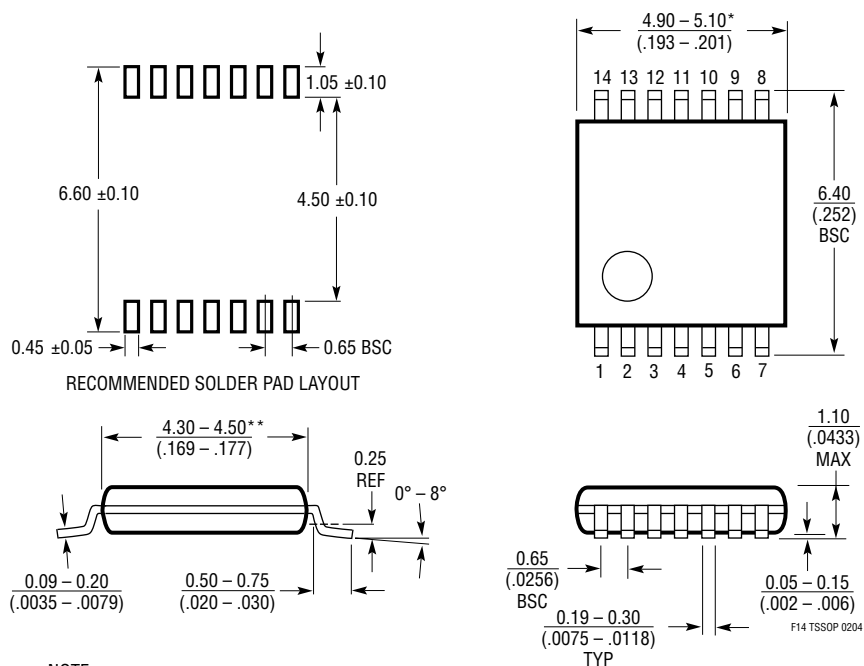
- NOTE:
1. DRAWING CONFORMS TO JEDEC PACKAGE OUTLINE MO-220 VARIATION (WEED-4)
  2. DRAWING NOT TO SCALE
  3. ALL DIMENSIONS ARE IN MILLIMETERS
  4. DIMENSIONS OF EXPOSED PAD ON BOTTOM OF PACKAGE DO NOT INCLUDE MOLD FLASH. MOLD FLASH, IF PRESENT, SHALL NOT EXCEED 0.15mm ON ANY SIDE
  5. NiPdAu PPF TERMINAL FINISH
  6. SHADED AREA IS ONLY A REFERENCE FOR PIN 1 LOCATION ON THE TOP AND BOTTOM OF PACKAGE



RECOMMENDED SOLDER PAD PITCH AND DIMENSIONS

## PACKAGE DESCRIPTION

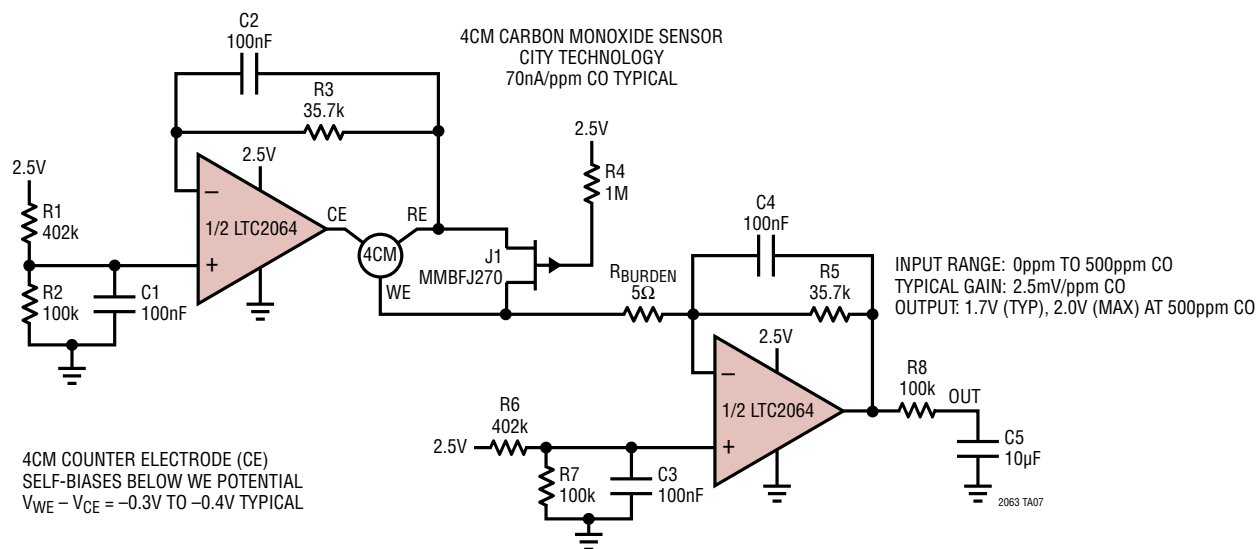
### F Package 14-Lead Plastic TSSOP (4.4mm) (Reference LTC DWG # 05-08-1650)



## REVISION HISTORY

| REV | DATE | DESCRIPTION                 | PAGE NUMBER |
|-----|------|-----------------------------|-------------|
| A   | 7/18 | Added LTC2064, fixed typos  | All         |
| B   | 4/20 | Added LTC2065 to data sheet | All         |

TYPICAL APPLICATION



RELATED PARTS

| PART NUMBER                                      | DESCRIPTION                                                     | COMMENTS                                                                                          |
|--------------------------------------------------|-----------------------------------------------------------------|---------------------------------------------------------------------------------------------------|
| <a href="#">ADA4051-1/ADA4051-2</a>              | Micropower, Single/Dual, Zero-Drift Operational Amplifier       | 7 $\mu$ A $I_S$ , 15 $\mu$ V $V_{OS}$ , 11.8V to 5.5V $V_S$ , 115kHz, RRIO                        |
| <a href="#">LTC2066/LTC2067/LTC2068</a>          | Micropower, Low IB Single/Dual, Zero-Drift Op Amps              | 2 $\mu$ A $I_S$ , 5 $\mu$ V $V_{OS}$ , 1.7V to 5.25V $V_S$ , 20kHz, RRIO                          |
| <a href="#">LTC2054/LTC2055</a>                  | Micropower, Single/Dual, Zero-Drift Operational Amplifier       | 130 $\mu$ A $I_S$ , 5 $\mu$ V $V_{OS}$ , 2.7V to 11 V $V_S$ , 500kHz, RR Output                   |
| <a href="#">ADA4522-1/ADA4522-2/ADA4522-4</a>    | 55V, Low Noise Zero-Drift Operational Amplifier                 | 900 $\mu$ A $I_S$ , 5.8nV/ $\sqrt{Hz}$ , 5 $\mu$ V $V_{OS}$ , 4.5V to 55V $V_S$ , 3MHz, RR Output |
| <a href="#">LTC2057/LTC2057HV</a>                | High Voltage-Low Noise Zero-Drift Operational Amplifier         | 4 $\mu$ V $V_{OS}$ , 1.2mA $I_S$ , 4.75V to 60V $V_S$ , 1.5MHz, RR Output                         |
| <a href="#">LTC2058</a>                          | 36V, Low Noise Zero-Drift Operational Amplifier                 | 5 $\mu$ V $V_{OS}$ , 1.2mA $I_S$ , 4.75V to 36V $V_S$ , 2.5MHz, RR Output                         |
| <a href="#">LTC2050/LTC2050HV</a>                | Zero-Drift Operational Amplifier                                | 3 $\mu$ V $V_{OS}$ , 1.5mA $I_S$ , 2.7V to 12V $V_S$ , 3MHz, RR Output                            |
| <a href="#">LTC2051/LTC2052</a>                  | Dual/Quad Zero-Drift Operational Amplifier                      | 3 $\mu$ V $V_{OS}$ , 1.5mA $I_S$ , 2.7V to 12V $V_S$ , 3MHz, RR Output                            |
| <a href="#">ADA4528-1/ADA4528-2</a>              | 5V Ultra Low Noise Zero-Drift Op Amps                           | 5 $\mu$ V $V_{OS}$ , 5.6nV/ $\sqrt{Hz}$ , 1.7mA $I_S$ , 2.2V to 5.5V $V_S$ , 4MHz, RRIO           |
| <a href="#">LT<sup>®</sup>1494/LT1495/LT1496</a> | 1.5 $\mu$ A Max, Over-The-Top Precision Operational Amplifier   | 1.5 $\mu$ A $I_S$ , 375 $\mu$ V $V_{OS}$ , 2.2V to 36V $V_S$ , 2.7kHz, RRIO                       |
| <a href="#">LT6003/LT6004/LT6005</a>             | 1.6V, 1 $\mu$ A Precision Rail-to-Rail Input and Output Op Amps | 1 $\mu$ A $I_S$ , 500 $\mu$ V $V_{OS}$ , 1.6V to 16V $V_S$ , 2kHz, RRIO                           |
| <a href="#">LT6023</a>                           | Micropower, Enhanced Slew Op Amp                                | 20 $\mu$ A $I_S$ , 20 $\mu$ V $V_{OS}$ , 3V to 30V $V_S$ , 40kHz                                  |
| <a href="#">LTC2053</a>                          | Precision, Rail-to-Rail, Zero-Drift, PGIA                       | 1.3mA $I_S$ , 10 $\mu$ V $V_{OS}$ , 2.7V to 12V $V_S$ , 200kHz, RRIO                              |
| <a href="#">LT5400</a>                           | Quad Matched Resistor Network                                   | 0.01% Matching, 8ppm/ $^{\circ}C$ Temp Drift , 0.2ppm/ $^{\circ}C$ Temp Matching                  |